Implementation of Single-Qubit Gates via Parametric Modulation in the Majorana Transmon

E. Lupo⁽⁰⁾,^{1,*} E. Grosfeld⁽⁰⁾,² and E. Ginossar⁽⁰⁾

¹Advanced Technology Institute and Department of Physics, University of Surrey, Guildford GU2 7XH,

United Kingdom

² Department of Physics, Ben-Gurion University of the Negev, Beer-Sheva 84105, Israel

(Received 6 July 2021; revised 23 January 2022; accepted 20 April 2022; published 23 May 2022)

We present a voltage gate-based method for controlling the Majorana transmon, using a sinusoidal modulation of the induced offset charge n_g . Working in the transmon regime and in the instantaneous eigenstates basis, we find the time evolution under this protocol that realizes tunable X-Z rotations. We optimize the parameters of the system for different single-qubit gates in both the laboratory frame and the qubit rotating frame, obtaining qubit control errors $1 - \mathcal{F}$ smaller than about 2×10^{-4} . In addition to this, we conduct an analysis of the effects of the charge noise, assuming wide-band 1/f additive noise in n_g , both for the free and the driven evolutions. For the free evolution, the relaxation and dephasing rates are calculated perturbatively, obtaining long dephasing times of the order of milliseconds at the system's sweet spots. For the driven case, the average fidelity for the X gate is obtained via a numerical simulation, demonstrating remarkable resilience.

DOI: 10.1103/PRXQuantum.3.020340

I. INTRODUCTION

Superconducting circuits based on the transmon qubit [1-3] are among the most studied platforms for quantum information processing, showing promising results in terms of coherent control and scalability [4,5]. Following their huge success, new designs [6-10] are continuously being proposed to accelerate the development of either fault-tolerant [11] or noisy intermediate-scale quantum (NISQ) computers [5]. These include ideas for hybrid platforms where new solid-state elements are embedded in the superconducting circuit to improve both their controllability and their sensitivity to various decoherence mechanism [12-18]. Specifically, embedding topological superconductors, which harbour collective topological excitations such as Majorana zero modes (MZMs) [19–21], into superconducting circuit architectures, could lead to new ways for detecting them and potentially to new qubit designs. Either semiconducting nanowires with strong spin-orbit coupling or topological insulator nanowires and nanoribbons represent promising candidates for the creation and manipulation of MZMs [22–33]. Several experimental studies show progress towards building topological Josephson junctions using indium-based semiconducting materials like InAs or InSb [34–39] or bismuth-based topological insulators such as Bi_2Se_3 and Bi_2Te_3 [40–44].

Because of their intrinsic topological protection, the introduction of MZMs in hybrid devices may be proven useful for quantum information processing [45–54]. Several works propose qubit designs and protocols for implementing topologically protected braiding operations, either by spatially moving the Majorana modes via electrostatic gates [45,53] or by applying equivalent methods such as Coulomb-assisted braiding [47,48] and projectivemeasurement based protocols [46,51,52]. These schemes rely on the precise adiabatic control of electrostatic gates, effective charging energies, or tunnel couplings to quantum dots, exposing the stored quantum information to multiple decoherence effects related to the use of nearby electrodes [55–59]. In addition to this, from an engineering point of view, these braiding-based proposed qubits are highly complex devices, and hence a simpler qubit design would be beneficial. Following this direction, an alternative approach for the realization of Majorana-based hybrid qubits [49,50,54,60] introduces a weak interaction

^{*}e.lupo@surrey.ac.uk

Published by the American Physical Society under the terms of the Creative Commons Attribution 4.0 International license. Further distribution of this work must maintain attribution to the author(s) and the published article's title, journal citation, and DOI.

energy E_M originating from the partial overlap of neighboring MZMs. When operating in the "Majorana transmon" regime $E_M \ll E_C \ll E_J$, with E_C and E_J the charging and Josephson energies of the circuit, the spectrum resembles that of a harmonic oscillator with each level doubled and each doublet well separated from the others [49,50]. The introduction of the coupling E_M inevitably sacrifices the full topological protection of the system. However, the electrostatic dipole coupling between levels of the same doublet is exponentially suppressed, making the lowest two energy levels protected from radiative decay. The embedding of this system in a circuit QED architecture has been shown to be a promising tool for the qubit readout [50,61] or in general, for a reliable detection method of the Majorana modes [29–31]. Recent works [50,54,62] also started to explore the challenge of controlling the qubit state. The high anharmonicity in the spectrum in principle means that fast gates could be obtained without introducing unwanted transitions to higher-energy levels; hence, the use of a transmission line resonator [50] has been proposed for the control of the qubit. Nonetheless, because of the said vanishing intradoublet dipole couplings and the symmetry of the interdoublet ones, a two-tone drive that exploits the transitions to higher doublets needs to be used to obtain coherent oscillations, leading to long gate times [50]. In other theoretical work [54] on Majorana-based qubits it was shown that coherent oscillations can arise from a combination of different parameters' switches starting and ending in the charging regime $E_C \gg E_J$. It was also recently suggested [62] to use multiple sweeps through an avoided crossing of the spectrum for the manipulation of MZMs in Josephson junctions, exploiting the Landau-Zener-Stückelberg interferometry effect. Other types of time-modulated parametric manipulations have also been considered for gubit readout in works on similar Majorana-based setups [63,64]. This raises the intriguing possibility that similar methods could be used to resolve the pending challenge of how to implement a universal set of fast, single-qubit gates in the Majorana transmon.

In this work, we propose a precise and systematic voltage gate-based method for the control of the Majorana transmon qubit exploiting the dynamical modulation of the induced offset charge parameter n_g , where n_g is measured in units of Cooper pair charge 2e, and consequentially analyze it under the effect of charge noise. The periodic modulation of such a parameter, in the Majorana transmon regime defined above, introduces a nonlinear driving term in the Hamiltonian of the lowest doublet's subspace that we show can be used to realize a set of high-fidelity single-qubit gates. Furthermore, we show that even if the parameter modulation itself represents a potential decoherence channel of the system, the analysis conducted for both the free and driven evolution under intrinsic 1/f charge noise effect yields long relaxation and dephasing times. This shows how the modulation of this specific internal parameter of the system, which is experimentally controlled via an external voltage bias $V_g \propto n_g$, can represent a possible alternative to the microwave control or other gate-based schemes.

The high anharmonicity of the system allows us to restrict the dynamics to the lowest-energy doublet of the spectrum. We employ the basis of the instantaneous eigenstates of this subspace and, making use of the counterrotating hybridized rotating-wave method approximation [65], we find the solutions of the model beyond the rotating-wave approximation regime and show that a sinusolidal modulation of $n_{g}(t)$ leads to an effective rotation of the qubit about an axis lying in the x-z plane. This rotation axis is indeed tunable via the other internal parameters E_M and E_J , thus making any single-qubit gate involving an X or Z rotation possible. The use of the instantaneous eigenstates of the Hamiltonian as the computational basis for the qubit instead of the parity states of the parent superconducting system obviates the need for tuning the interaction energy E_M to the charging regime [54] for the initialization and readout stages, reducing any unwanted transitions. When the parameters involved are optimized, we obtain an implementation of an X gate with control error (infidelity $(1 - \mathcal{F}_G) \sim 10^{-4}$, which is in accordance with the threshold for implementing fault-tolerant quantum computation [11]. The hybridization due to E_M makes the system itself sensitive to modulations of $n_g(t)$ over the range [0, 1/2]; hence, we study the effect of additive, Gaussian 1/f noise fluctuations on the offset charge parameter n_{g} . Other sources of charge noise can of course be present in the system and have been analyzed elsewhere [66,67]; however, here we decide to focus on noise that is intrinsic to the system and happening on relevant timescales. We use a perturbative analysis of the Liouville equation to derive the relaxation and dephasing rates for the free evolution and we find that the system presents a sweet spot at $n_g = 0$, with dephasing time $T_{\phi} \sim 1.4 - 14$ ms that is typically beyond the current state-of-the-art transmon [4]. This is also significant because $n_g = 0$ represents the initial and final values for the gate protocol, and thus also the idle point when implementing a quantum algorithm. For the driven evolution, the additive noise is simulated numerically during the protocol, leading to a reduction of the X gate fidelity smaller than 0.01%. The protocol also shows low sensitivity to systematic errors on the initial value of the offset charge $n_{\alpha}(0)$ and on the parameters E_M and E_J .

The paper is structured as follows. Section II presents an overview of the system and the protocol chosen. In Sec. III A an effective rotation of the qubit about a tunable axis of the x-z plane is derived. Section III B extends this method for the implementation of various singlequbit gates. Finally, Sec. IV presents the effect of the 1/fcharge noise on the system. In Sec. V we summarize and conclude.

II. THE MAJORANA TRANSMON QUBIT IN THE INSTANTANEOUS EIGENBASIS

The hybrid system studied is based on the basic charge superconducting qubit where a Josephson junction (JJ) is capacitively coupled to an external voltage gate V_g (also known as a Cooper pair box). In order to introduce topological states in the system, a nanowire that can host Majorana zero modes in its topological phase is placed across the JJ, so that the topological phase can be induced just in the proximity of the right and left superconducting leads and the equivalent of two topological nanowires are created on top of them. The nanowire used can be either a semiconductor with strong spin-orbit coupling or a topological insulator, two materials where, in the presence of an external magnetic field, the formation of these topological excitations at their edges has been predicted [22,24–26]. Figure 1(a) presents a scheme of the hybrid system hosting the localized Majorana zero modes, represented at the edges of the topological nanowires. Besides the energy contributions H_T coming from the superconducting part, the model includes the tunneling interaction term H_M originated from the partial overlap of the neighboring MZMs near the Josephson junction. This term can be tuned by a local voltage gate at the Josephson junction [49] and



FIG. 1. Overview of the Majorana transmon (MT) system. (a) Schematic setup of the MT, with the two topological nanowires hosting Majorana zero modes (MZMs) γ_1 - γ_4 placed on top of the leads that form the Josephson junction in a charge qubit. In this way, the two topological superconductors present the charge qubit Hamiltonian as a bulk Hamiltonian. An interaction term of the two neighboring MZMs γ_2 and γ_3 is introduced in the system and hybridizes states with different fermionic parity. There is no charge transfer between the electrostatic gates at potential difference V_{g} (colored in orange) and the other parts of the system. (b) Schematic representation of the qubit energy dispersion and control. The qubit subspace coincides with the lowest doublet of the MT and it is represented by the red lines, while the dotted black lines are the uncoupled transmon levels. The system $H_T + H_M$ presents an avoided crossing at $n_g = 1/4$ so that a sinusoidal modulation of the internal parameter n_g (i.e., the voltage gate V_g) sweeping across the range [0, 0.5] will introduce nonadiabatic transitions in the system.

hybridizes the eigenstates $|\Psi_k^{e/o}\rangle$ of H_T with different relative parity, that is, the parity of the relative number of fermions across the Josephson junction. We work in the transmon regime $E_J \gg E_C$, with E_J and E_C the Josephson and charging energies of the system, respectively, where the eigenstates of H_T can be approximated by the eigenstates of the harmonic oscillator at the zeroth-order perturbation theory [3]. In this regime, when the Majorana interaction energy E_M is small compared to the charging energy, $E_M \ll E_C$, the term hybridizes only eigenstates of H_T within the same energy band k, creating a doublet structure in the spectrum. The total Hamiltonian $H = H_T + H_M$ can be written into a block diagonal form in the basis of $|\Psi_k^{e/o}\rangle$, each block representing the subspace at fixed transmon band k [50]:

$$H^{(k)} = \begin{pmatrix} \epsilon_k^{h.o.} + t_k \cos\left(2\pi n_g\right) & E_M \\ E_M & \epsilon_k^{h.o.} - t_k \cos\left(2\pi n_g\right) \end{pmatrix}.$$
(1)

Here $\epsilon_k^{h.o.}$ is the *k*th energy level of a harmonic oscillator with frequency $\sqrt{8E_CE_J}$ and the term $t_k \cos(2\pi n_g)$ is the transmon energy dispersion derived with the WKB treatment, with $t_k \propto E_C (-1)^{k+1} (E_J / E_C)^{k/2 + 3/4} e^{-\sqrt{8E_J / E_C}}$, $k \in$ N. In particular, n_g is a dimensionless parameter representing the induced offset charge between the superconducting islands, in units of the Cooper pair charge 2e, and can include the contribution coming from the action of an external electric voltage on the qubit, $V_g \propto n_g$ (additional details about the solutions of this model can be found in Appendix A). It should be noted that the scheme shown in Fig. 1 is consistent with the use of the parameters regime $E_M \ll E_C \ll E_J$. The energies E_M and E_J are in fact both tunneling parameters and so they are directly proportional to the nanowire and the superconducting junction crosssectional area, respectively. More realistic modelings of devices leading to Eq. (1) exist in the literature [29,54] and support its validity in the aforementioned parameter regime.

One of the consequences of working with two very different energy scales E_M and E_J is the high anharmonicity gained in the spectrum, given by $\alpha_r = (\epsilon_1^{h.o.} - \epsilon_0^{h.o.})/2E_M = \sqrt{2E_CE_J}/E_M \gg 1$. The lowest doublet remains well isolated from the rest of the spectrum and can form the qubit computational subspace. Another important feature of this model is the exponential suppression of the intradoublet dipole interaction with the electrostatic field. This makes the chosen qubit subspace robust against radiative decay, but it forces the use of higher transmon bands when it is controlled via a superconducting cavity [50]. Here we aim to control the qubit without exiting the computational subspace, so that the Hamiltonian takes the form

$$H \equiv H^{(k=0)} = t_0 \cos\left(2\pi n_g\right)\sigma_z + E_M \sigma_x, \qquad (2)$$

where we have dropped a constant term $\epsilon_0^{h.o.}$, and $t_0 < 0$. The solutions of the qubit Hamiltonian (2) can be expressed in terms of the states at fixed parity $|\Psi^{e/o}\rangle \equiv |\Psi_{k=0}^{e/o}\rangle$ as rotated-parity states, i.e.,

$$|\Psi^{+}\rangle = \sin\eta |\Psi^{e}\rangle + \cos\eta |\Psi^{o}\rangle, \qquad (3a)$$

$$|\Psi^{-}\rangle = \cos\eta |\Psi^{e}\rangle - \sin\eta |\Psi^{o}\rangle, \qquad (3b)$$

$$E_{\pm} = \pm \sqrt{E_M^2 + t_0^2 \cos^2 (2\pi n_g)},$$
 (3c)

where $\eta[n_g] \equiv \frac{1}{2} \operatorname{atan2}[E_M, |t_0| \cos(2\pi n_g)]$ is the mixing angle. We note that the system presents an avoided crossing at $n_g = 1/4$ [see Fig. 1(b)], and thus we decide to study the effect of a nonadiabatic modulation of such an internal parameter via the external gate V_g . We derive the effective time-dependent Hamiltonian $H_I(t)$ of the system in the eigenstates basis $\{|\Psi^+\rangle, |\Psi^-\rangle\}$ when a generic modulation $n_{\varphi}(t)$ is applied. We call $|\psi(t)\rangle$ and $|\psi_{I}(t)\rangle$ the states of the system respectively expressed in the bases $\{|\Psi^e\rangle, |\Psi^o\rangle\}$ and $\{|\Psi^+\rangle, |\Psi^-\rangle\}$, while $R_v[\eta(t)] \equiv e^{i\eta(t)\sigma_y}$, with $\eta(t) \equiv \eta[n_g(t)]$ the mixing angle defined above, is the change-of-basis transformation that connects them. Inserting $|\psi(t)\rangle = R_{\nu}[\eta(t)] |\psi_{I}(t)\rangle$ into the Shrödinger equation for $|\psi(t)\rangle$, the effective Hamiltonian for $|\psi_I(t)\rangle$, $H_I(t) \equiv R_v^{-1}[\eta(t)]H(t)R_v[\eta(t)] - i\hbar R_v^{-1}[\eta(t)]\partial_t R_v[\eta(t)], \text{ is }$ obtained as

$$H_{I}(t) = -\sqrt{E_{M}^{2} + t_{0}^{2}\cos^{2}(2\pi n_{g}(t))}\sigma_{z} + \frac{h E_{M}t_{0}\sin[2\pi n_{g}(t)]}{2[E_{M}^{2} + t_{0}^{2}\cos^{2}(2\pi n_{g}(t))]}n_{g}'(t)\sigma_{y} \qquad (4)$$

with $n'_g(t) \equiv \partial_t n_g(t)$. This demonstrates that $n_g(t)$ introduces a direct driving term between the two qubit eigenstates $|\Psi^+\rangle$ and $|\Psi^-\rangle$. To maximize the effect of this nonadiabatic modulation, we can choose a function of $n_g(t)$ that sweeps multiple times through the range [0, 1/2], passing by the avoided crossing at $n_g = 1/4$. A condition for the sweeping speed can be calculated to reduce the leakage to higher doublets of the system. Denoting by $|\Psi_n\rangle$ and E_n a generic eigenstate and eigenenergy of the Hamiltonian $H = H_T + H_M$, this condition is given by [68]

$$\frac{1}{n'_g(t)} \gg \max \left| \frac{[\partial H/\partial n_g]_{mn}}{(\Delta E_{mn})^2} \right| \sim \frac{1}{E_J} \left(\frac{E_J}{32E_C} \right)^{1/4},$$

where $[\partial H/\partial n_g]_{mn} = \langle \Psi_m | \partial H/\partial n_g | \Psi_n \rangle$ and $\Delta E_{mn} = E_m - E_n$. Because of the fact that $E_J \gg E_M$, two very different energy scales are present in the system, which are the interdoublet gap energy $\Delta \epsilon_{01}^{h.o.} = \epsilon_1^{h.o.} - \epsilon_0^{h.o.}$ and

the intradoublet energy $2E_M$, with $\Delta \epsilon_{01}^{h.o.} \gg 2E_M$. Thus, a sweeping speed $n'_g(t)$ can be chosen in order to maintain the nonadiabatic transitions within the qubit subspace.

III. THE GATE PROTOCOL

A. System dynamics under parametric modulation

Hamiltonian (4) describes the dynamics originating from a generic time-dependent modulation of the parameter n_g , using $\{|\Psi^+\rangle, |\Psi^-\rangle\}$ as the computational basis. We now aim to find a configuration of the system that results in the implementation of a specific single-qubit gate *G* after a time t_F . To gain more understanding of the dynamics, we analyze $H[n_g(t)]$ in the fixed parity basis $\{|\Psi^e\rangle, |\Psi^o\rangle\}$, Eq. (2), and project it onto the eigenstates basis at the end of the protocol. Also, in this section the convention $\hbar = 1$ is used. We choose to modulate the n_g parameter as a sinusoidal function centered at the avoided crossing $n_g = 1/4$ and with amplitude 1/4:

$$n_g(t) = \frac{1}{4} [1 - \cos(\omega t)].$$
 (5)

Here ω is the frequency of the oscillation and $T = \pi/\omega$ represents half of the period, i.e., the time it takes n_g to sweep the range [0, 1/2] once. Since the applied external voltage V_g is directly proportional to n_g , both share the same time dependence. In particular, both start and end smoothly at zero, making the signal straightforward to implement in realistic setups (see Appendix B). The frequency of the signal is suitably optimized later depending on the single-qubit gate one wants to implement. Using this modulation, the time-dependent Hamiltonian of the system in the fixed parity basis { $|\Psi^e\rangle$, $|\Psi^o\rangle$ } is obtained as

$$H(t) = -|t_0| \sin[(\pi/2)\cos(\omega t)]\sigma_z + E_M \sigma_x \qquad (6)$$

with $\sigma_{i=x,y,z}$ being the Pauli operators. In this section we make use of the Jacobi-Anger expansions [69],

$$e^{iz\cos\theta} \equiv J_0(z) + 2\sum_{n=1}^{\infty} (-1)^n J_{2n}(z)\cos(2n\theta)$$

$$-2i\sum_{n=1}^{\infty} (-1)^n J_{2n-1}(z)\cos[(2n-1)\theta], \quad (7a)$$

$$e^{iz\sin\theta} \equiv J_0(z) + 2\sum_{n=1}^{\infty} J_{2n}(z)\cos(2n\theta)$$

$$+2i\sum_{n=1}^{\infty} J_{2n-1}(z)\sin[(2n-1)\theta], \quad (7b)$$

to find an approximation of the system's dynamics. In particular, we employ Eq. (7a) to express the sinusoidal term in Hamiltonian (6) as a series expansion in cosines, and keep the zeroth-order term:

$$H' = -2|t_0|J_1(\pi/2)\cos(\omega t)\sigma_z + E_M\sigma_x.$$
 (8)

The system is now analogous to a two-level system coupled to a sinusoidal external drive. While the ordinary rotating-wave approximation is valid only for very small values of the ratio $2t_0J_1(\pi/2)/E_M$, we apply the counterrotating hybridized rotating-wave (CHRW) method [65] that is valid in a much larger area of the parameters' space. Instead of removing progressively the counter-rotatingwave contributions at different orders of harmonics as is done for obtaining the Bloch-Siegert Hamiltonian [70], the CHRW method uses a transformation that contains the contributions of all the harmonics, as we now detail. Letting $A = 2|t_0|J_1(\pi/2)$, we define the unitary transformation

$$\mathcal{T} = e^{-i(A/\omega)\kappa\sin(\omega t)\sigma_z},\tag{9}$$

with κ a free parameter that will be conveniently chosen later [see Eq. (12)]. Again using the Jacobi-Anger expansions, Eq. (7b), the transformed Hamiltonian $\tilde{H} = TH'T^{\dagger} + i(\partial_t T)T^{\dagger}$ takes the form

$$\tilde{H} = -A(1-\kappa)\cos(\omega t)\sigma_z + E_M\cos\left(\frac{2A\kappa}{\omega}\sin(\omega t)\right)\sigma_x + E_M\sin\left(\frac{2A\kappa}{\omega}\sin(\omega t)\right)\sigma_y \simeq -A(1-\kappa)\cos(\omega t)\sigma_z + E_M J_0\left(\frac{2A\kappa}{\omega}\right)\sigma_x + 2E_M J_1\left(\frac{2A\kappa}{\omega}\right)\sin(\omega t)\sigma_y,$$
(10)

where we have neglected the higher-order harmonic terms. The coefficients of the σ_z and σ_y are time dependent; hence, it is useful to work in the basis of σ_x , and express the approximated Hamiltonian (10) in terms of its ladder operators $\sigma_+^{(x)}$ and $\sigma_-^{(x)}$, with $\sigma_{+,-}^{(x)} = \frac{1}{2} (\sigma_z \mp i\sigma_y)$:

$$\tilde{H} \simeq E_M J_0 \left(\frac{2A}{\omega}\kappa\right) \sigma_x + \left\{-\frac{A}{2}(1-\kappa) + E_M J_1 \left(\frac{2A}{\omega}\kappa\right)\right\} (e^{i\omega t}\sigma_+^{(x)} + e^{-i\omega t}\sigma_-^{(x)}) - \left\{\frac{A}{2}(1-\kappa) + E_M J_1 \left(\frac{2A}{\omega}\kappa\right)\right\} (e^{i\omega t}\sigma_-^{(x)} + e^{-i\omega t}\sigma_+^{(x)}).$$
(11)

We choose the variable κ such that the counter-rotating terms $e^{i\omega t}\sigma_{+}^{(x)}$ and $e^{-i\omega t}\sigma_{-}^{(x)}$ of Eq. (11) vanish:

$$A(1-\kappa) - 2E_M J_1\left(\frac{2A}{\omega}\kappa\right) = 0.$$
(12)

In this way, after neglecting the higher-order harmonic terms, the CHRW-approximated Hamiltonian takes the form

$$\tilde{H}_{\text{CHRW}} \simeq E_M J_0(z) \sigma_x$$

- $2E_M J_1(z) (e^{-i\omega t} \sigma_+^{(x)} + e^{+i\omega t} \sigma_-^{(x)}), \qquad (13)$

where we have defined $z \equiv 2A\kappa/\omega$. We set $\Delta = 2E_M J_0(z)$ and $g = 8E_M J_1(z)$, and we express \tilde{H}_{CHRW} in the rotating frame of the drive as

$$\tilde{H}_{\rm CHRW}^{\rm (RF)} = V \tilde{H}_{\rm CHRW} V^{\dagger} + i(\partial_t V) V^{\dagger}$$
$$= \frac{\Delta - \omega}{2} \sigma_x - \frac{g}{4} (\sigma_+^{(x)} + \sigma_-^{(x)}), \qquad (14)$$

where $V = e^{+i(\omega/2)t\sigma_x}$. Equation (14) is equivalent to the Hamiltonian of a spin placed in a constant magnetic field [70], so that it yields the time-evolution operator

$$\begin{split} \tilde{U}_{\rm CHRW}^{\rm (RF)} &= \cos\left(\frac{\Omega}{2}t\right) \mathbb{I} - i\sin\left(\frac{\Omega}{2}t\right) \frac{2\tilde{H}_{\rm CHRW}^{\rm (RF)}}{\Omega} \\ &= \cos\left(\frac{\Omega}{2}t\right) \mathbb{I} + i\sin\left(\frac{\Omega}{2}t\right) \left\{\frac{g}{2\Omega}\sigma_z - i\frac{(\Delta-\omega)}{\Omega}\sigma_x\right\}, \end{split}$$
(15)

with $\Omega = \sqrt{(\Delta - \omega)^2 + g^2/4}$. In order to express the dynamics in the instantaneous eigenstates basis, we transform the evolution operator back into the laboratory frame, $\tilde{U}_{\text{CHRW}} = e^{-i(\omega/2)t\sigma_x}\tilde{U}_{\text{CHRW}}^{(\text{RF})}$, we add the phase accumulated from the first transformation, and we rotate the evolution into the eigenstates basis $\{|\Psi^+\rangle, |\Psi^-\rangle\}$ using $R_y[\eta(t)] = e^{i\eta(t)\sigma_y}$, with $\eta(t) = \frac{1}{2}\operatorname{atan2}(E_M, |t_0|\sin[(\pi/2) \cos(\omega t)])$, as defined in Sec. II. In this way, the time evolution operator in the instantaneous eigenstates' basis takes the form

$$U_I(t) \simeq R_y^{-1}[\eta(t)] \mathcal{T}^{\dagger} V^{\dagger} \tilde{U}_{\text{CHRW}}^{(\text{RF})}(t) R_y[\eta(0)].$$
(16)

We can now see what the evolution looks like after *n* oscillations, i.e., for $\omega t_F = n \cdot 2\pi$ or, equivalently, $t_F = 2nT$ (*T* was defined earlier as half of the period of oscillation). Because of the periodicity of \mathcal{T} and *V*, these two operators become proportional to the identity operator I at t = 2nT, explicitly $\mathcal{T}^{\dagger}(2nT) = I$ and $V^{\dagger}(2nT) = (-1)^n I$. For the same reason, we have $\eta(2nT) = \eta(0) \equiv \eta_0$. This leads to the following expression for the evolution operator:

$$U_{I}(2nT) \simeq (-1)^{n} R_{y}^{-1}[\eta_{0}] \tilde{U}_{\text{CHRW}}^{(\text{RF})}(2nT) R_{y}[\eta_{0}].$$
(17)

As $\tilde{U}_{CHRW}^{(RF)}(2nT)$ contains only σ_z and σ_x terms, and as the rotation R_y about the y axis operates within the x-z plane, $U_I(2nT)$ represents a rotation about an axis that lies in this

said plane. This means that potentially, for specific values of the parameters of the system, this protocol can generate single-qubit gates that include any X or Z rotations. To see how this protocol can represent a specific gate operation G, the fidelity $\mathcal{F}_G = \frac{1}{4} |\operatorname{Tr}(U_I^{\dagger}(t)G)|^2$ can be computed. For the \mathcal{F}_X , we get

$$\mathcal{F}_X(2nT) \simeq \frac{|(\Delta - \omega)|t_0| - E_M g/2|^2}{(E_M^2 + t_0^2)(g^2/4 + (\Delta - \omega)^2)} \sin^2(n\Omega T).$$
(18)

This expression can be used to find the optimal values for $T = \pi/\omega$, E_M and E_J (represented by $|t_0|$). Also, specifically for the X and the Hadamard gates, exact conditions for these parameters can be found (see Appendix C for details). As an example, Fig. 2 shows the implementation of the X gate when Eq. (18) is maximized for n = 2, i.e., to obtain an X gate after two oscillations ($t_F = 4T$). For the simulation, we use values of charging and Josephson energies E_C and E_J that are realistic for a superconducting



FIG. 2. Implementation of an n_g -modulated X gate in the Majorana transmon system, when \mathcal{F}_X is maximized for $t_F = 4T$. (a) Evolution of the populations for the lowest two states of the Majorana transmon as a function of t/T, with $T = \pi/\omega$, using the protocol described in Sec. III A. The Black dashed lines indicate the quantity calculated without the CHRW approximation. (b) Plot of the n_g signal sent to the qubit. (c) Fidelity $\frac{1}{4}|\mathrm{Tr}(U_I^{\dagger}X)|^2$ during the operation, with its maximal value at t = 4T. (d) Evolution of the state on the Bloch sphere, also showing the evolution of the instantaneous eigenstates in the parity basis represented in blue and orange. (e) Evolution of the state in the parity basis of $|\Psi^e\rangle$ and $|\Psi^o\rangle$. For all panels, $E_C/h = 0.4$ GHz, $E_J = 10E_C$, and $E_M = 0.012E_C$.

circuit apparatus. The resulting frequency of oscillation for $n_{\sigma}(t)$ is of the order of tens of megahertz, which should be experimentally achievable given that pulses at much higher frequencies have already been implemented in the past on the first charge qubits [71]. A more detailed argument about the experimental implementation of this protocol can be found in Appendix B. In Fig. 2(a) it can be seen that the evolution of the qubit level populations under the CHRW approximation, extracted from Eq.(16), matches the exact evolution quite accurately. Figure 2(b) presents the shape of the n_g signal that is sent for implementing the gate, while in Fig. 2(c) the fidelity $\mathcal{F}_G = \frac{1}{4} |\text{Tr}(U_I^{\dagger}(t)G)|^2$ is plotted, clearly showing its maximal value at t = 4T. In addition to this estimates, the evolution of the state of the system and the eigenstates at each value of $t \in [0, 4T]$ are shown on the Bloch sphere in Figs. 2(d) and 2(e). Since we start and end the protocol at integer numbers of n_g oscillations, we can note that this specific X gate with $t_F = 4T$ already includes its half rotation \sqrt{X}^{\dagger} at its midway point t = 2T(dashed red arrow on the same Bloch sphere), a singlequbit gate operation that can be useful when implementing a quantum algorithm.

B. Other single-qubit gates and initialization

Using the same n_g modulation, Eq. (5), other gates involving X or Z rotations can be obtained. Since we are working in the laboratory frame, any rotation about the z axis is efficiently implemented during a free evolution. Hence we focus on other types of single-qubit gates useful for quantum computing, which are the X and the Hadamard gates. Figure 3 compares the optimization plots for the X gate with $t_F = 4T$ and the Hadamard gate with $t_F = 2T$, and shows the implementation of the Hadamard gate on the Bloch sphere starting from the ground state $|\Psi^-\rangle$. Table I shows the optimal values for these gates with different t_F . To obtain these values, we fix $E_J/E_C = 10$ for all the calculations. In fact, if we expand κ , Eq. (12), up to the second order in $|t_0|$ [65],

$$\kappa \simeq \frac{\omega}{\omega + 2E_M} \left(1 + \frac{4J_1^2(\pi/2)E_M|t_0|^2}{(\omega + 2E_M)^3} \right)$$

we can use it to express the quantity Ω/ω in terms of $2E_M/\omega$ and $|t_0|/\omega$ as

$$\frac{\Omega}{\omega} \simeq \left[\left(\frac{2E_M}{\omega} - 1 \right)^2 + \frac{8J_1^2(\pi/2)}{2E_M/\omega + 1} \frac{|t_0|^2}{\omega^2} \frac{2E_M}{\omega} - \frac{8J_1^4(\pi/2)}{(2E_M/\omega + 1)^3} \frac{|t_0|^4}{\omega^4} \frac{2E_M}{\omega} \right]^{1/2},$$
(19)

and the optimal points for the fidelity lie along the resonant curves of fixed Ω/ω [solid, white lines in Figs. 3(a) and 3(b)]. Since $t_0(E_C, E_J)$ exponentially decreases as a



FIG. 3. Optimization graphs and Bloch sphere evolution in the laboratory frame for the X and Hadamard H gates with protocol time $t_F = 4T$ and $t_F = 2T$, respectively. (a) Optimization graph representing the fidelity for the X gate as a function of $2E_M/\omega$ and A/ω , with $A = 2|t_0|J_1(\pi/2)$. The red dot indicates the optimal point used for the evolution in Fig. 2. (b) Optimization graph representing the fidelity for the Hadamard gate as a function of $2E_M/\omega$ and A/ω , with $A = 2|t_0|J_1(\pi/2)$. The blue dot indicates the optimal point of \mathcal{F}_H in the laboratory frame. The optimal point for \mathcal{F}_X is kept in red for comparison. In both (a) and (b) the calculation is done using the CHRW approximation. The white lines represent the resonances and antiresonances of the sinusoidal component of the two fidelities: $\sin(n\Omega T) = 1$ (solid lines) and $\sin(n\Omega T) = 0$ (dashed lines). The black dotted line represents the curve along which the gate can be optimized by only changing the frequency, keeping E_J and E_M fixed at the values optimized for the X gate, in case the switch between the two gates is needed. (c) Evolution on the Bloch sphere of a state starting in the ground state $|\Psi^-\rangle$ using the optimal parameters for the Hadamard gate [blue dot in (b)]. For all panels, the charging and Josephson energies are $E_C/h = 0.4$ GHz and $E_J = 10E_C$.

function of E_J/E_C , the value $E_J/E_C = 10$ is chosen to balance between having short gate times (high values of the frequency of oscillation ω) and remaining in the transmon regime $E_J \gg E_C$.

Either the X or the Hadamard gate can be chosen for implementing quantum algorithms in the system. In fact, given that we can obtain arbitrary z-axis rotations under free evolution, two possible finite single-qubit gate sets [72,73] are the standard set of $\{H, S, T\}$ or the set consisting of the Pauli matrices and the $\pi/8$ gate, $\{X, Y, Z, T\}$, with the Pauli Y gate generated using the composition of the other two, Y = -iXZ. Working in the laboratory frame has the advantage of not having to deal with internal parameter switching when changing the gates, because the parameters E_J and E_M need to be optimized only for the X (and consequently \sqrt{X}^{\dagger}) or the H gate, depending on the singlequbit set chosen. On the other hand, it requires precise timing during idle times, since in between two gates or algorithms the qubit has to complete an integer number of $2\pi z$ rotations.

Alternatively, the n_g protocol can be studied in the rotating frame of the qubit, where the evolution operator, Eq. (17), takes the form $U_I^{\text{RF}}(2nT) = e^{-in\Omega_q T\sigma_z} U_I(2nT)$ with $\Omega_q = 2\sqrt{t_0^2 + E_M^2}$. It this case the same type of n_g modulation can be used to produce gates representing finite z rotations. Table II shows the optimized values of the fidelity and the parameters for the gates mentioned above. Note that the phase gate can be performed using the $\pi/8$ gate, $S = T_{\pi/8}^2$. The optimization plots and evolution on the Bloch sphere for these gates can be found in Appendix C. Working in this frame surely removes the need of precise timing during idle times. However, since each gate has different optimized values for E_M , the tuning of this internal parameter is needed when implementing a sequence of single-qubit gates. When a gate operation G is applied to the qubit, before implementing the following \hat{G} operation, the E_M parameter needs to be switched from the value optimized for G to that optimized for \tilde{G} , keeping n_g fixed at $n_g = 0$. This operation has to be done necessarily adiabatically in order to avoid unwanted transitions

TABLE I. Table of optimized values of E_M/E_C and T for different gates and t_F at fixed $E_J/E_C = 10$, in the laboratory frame. The Z and $\pi/8$ are not indicated here because they can be obtained by exploiting the qubit's free evolution. For all calculations, $E_C/h = 0.4$ GHz. The parameter values are suitably rounded to ensure a precision at the sixth digit for the unit fidelities (CHRW) and at the fourth digit for all the other values of \mathcal{F} . Some of these optimal values are indicated in the optimization plots of Fig. 3: with a red dot for the X gate with $t_F = 4T$ and a blue dot for the Hadamard gate with $t_F = 2T$.

		Wit	th CHRW	Without CHRW			
Gate	t_F	$\mathcal{F}_{\text{Gate}}(t_F)$	E_M/E_C	T_{Gate} (ns)	$\mathcal{F}_{\text{Gate}}(t_F)$	E_M/E_C	T_{Gate} (ns)
X	4T	1	0.012	189.3	0.9998	0.012	189.8
Χ	2T	1	0.005	167.9	0.9997	0.005	169.4
Hadamard	2T	1	0.00759	186.5	0.9998	0.00779	184.4

TABLE II. Table of optimized values of E_M/E_C and T for different gates and t_F in the rotating frame at the qubit frequency. For all calculations, $E_C/h = 0.4$ GHz and $E_J/E_C = 10$. The parameter values are suitably rounded to ensure a precision at the sixth digit for the unit fidelities (CHRW) and at the shown significant digit for all the other values of \mathcal{F} . For the optimization plots and the evolution in the Bloch sphere, see Appendix C.

Gate (rotating frame)		With CHRW			Without CHRW		
	t_F	$\mathcal{F}_{\text{Gate}}^{\text{RF}}(t_F)$	E_M/E_C	T_{Gate} (ns)	$\mathcal{F}_{\text{Gate}}^{\text{RF}}(t_F)$	E_M/E_C	T_{Gate} (ns)
X	4T	0.99995	0.012	189.0	0.99997	0.012	189.5
\sqrt{X}^{\dagger}	2T	0.99997	0.012	94.5	0.99992	0.012	95.1
Ζ	4T	1	0.00626	223.7	1	0.00626	223.7
Hadamard	6T	0.963	0.0063	596.0	0.954	0.00627	599.2
Hadamard	8T	0.982	0.00944	571.4	0.978	0.00941	573.6
$T^{\dagger}_{\pi/8}$	4T	1	0.00898	340.0	1	0.0089	342.2

between the qubit levels. Conditions and estimates for the required switching time are derived in Appendix D. When choosing the Pauli-based universal gate set in the rotating frame, both methods can lead to high fidelity gates, with maximum control errors $1 - \mathcal{F}_G$ of 2×10^{-4} . However, in the rotating frame of the qubit the z rotations turn out to be slower than during the free evolution. In fact, using the optimized values for the X gate referred in Table I in the laboratory frame, the free evolution of the qubit with a frequency $\Omega_q = 2\sqrt{t_0^2 + E_M^2}$ leads to a Z gate (i.e., a π rotation about the z axis) in about 50 ns. In contrast, in the rotating frame, where the Z gate is performed using the n_{g} protocol, the calculated gate time after two periods (4T)results to be about 200 ns (see Table II and Appendix C for details). In the end, it is important to comment on the possible initialization process for the gate. The protocol in fact relies on the initial value of the offset charge, $n_g(0) = 0$. The value of n_g is hard to calibrate for $E_J \gg E_M$, but it can be easily tuned in the charging regime. Hence, a possible initialization protocol can be to start in a regime where $E_J \sim E_C$ and $E_M > 0$, calibrating $n_g(0)$ and moving the value of E_J adiabatically back to the working regime.

IV. CHARGE NOISE EFFECTS IN THE SYSTEM

In the previous section we showed how the modulation of n_g can be used to control the system. Unfortunately, this also means that charge noise affecting this variable can potentially cause decoherence. This kind of noise is typical of superconducting devices and can come from different sources. In this work we focus on the effect of the 1/f noise on n_g , which is intrinsic to the system since it is theorized to be coming from the coupling to random charge fluctuators [74]. The other intrinsic source of noise involved in the charge noise is telegraph noise due to quasiparticle poisoning that will not be considered here. In fact, even if the parity switching time is not known for systems that are theorized to carry Majorana quasiparticles, it has been measured in the range 1–10 μ s in Josephson junction-based devices [75], and there has been recent evidence of a parity switching time of about 160 μ s for a semiconducting nanowire-based system [76]. These values are relatively larger than the gate time of our protocol, and hence we can focus on the analysis of the effect of the 1/fnoise. Once the coupling with the noise source is assumed weak, the main effect of this dissipation channel can be considered to be a classical stochastic fluctuation of the parameter involved and can be characterized through the power spectral density (PSD) of the noise process [4,74]. Stochastic noise modifies the dynamics of a two-level system depending on which component of the Bloch-sphere vector it is affecting. When the Hamiltonian presents the noise fluctuations in the σ_x or σ_y term, the dynamics is affected along the z axis of the Bloch sphere and leads to relaxation. On the other hand, fluctuations in the σ_{z} term of the Hamiltonian affects the dynamics on the x-y plane, leading to pure dephasing. These dissipation processes manifest themselves in the dynamics of the density matrix of the system. In particular, when the noise in the Hamiltonian is "well behaved" (i.e., short correlated, with no singularity in the spectrum), as it is for white noise, either the Bloch-Redfield theory [77,78], the Born-Markov master equation approach [79], or the weak-damping path integral approach [80-82] can be used to model the dynamics and lead to an exponential decay for both the energy levels' populations and the density matrix's coherence terms. The 1/f noise is usually introduced as a longitudinal fluctuation in the Hamiltonian [4,74]. However, in some works transverse contributions have also been considered, and due to the fact that relaxation is a resonant phenomenon, a perturbative (diagrammatic) technique seems to lead, for the transverse component of the 1/f noise, to the same result as the Bloch-Redfield approach [83,84]. For a general, two-level system under free evolution starting from $\psi(t=0) = [c_0, c_1]^T$, assuming that the terms containing correlations between transverse and longitudinal components of the noise can be neglected and in the limit of zero temperature, the time-dependent density matrix of $\psi(t)$ under noise fluctuations takes the form:

$$\rho_{\psi}(t) = \begin{pmatrix} \frac{1}{2} [1 - (|c_1|^2 - |c_0|^2)e^{-\Gamma_1 t}] & c_0 c_1^* e^{-\chi(t)} e^{-\frac{1}{2}t} e^{i\delta\omega t} \\ c_0^* c_1 e^{-\chi^*(t)} e^{-(\Gamma_1/2)t} e^{-i\delta\omega t} & \frac{1}{2} [1 + (|c_1|^2 - |c_0|^2)e^{-\Gamma_1 t}] \end{pmatrix},$$
(20)

where the factors $e^{-\Gamma_1 t}$ and $e^{-(\Gamma_1/2)t}$, with Γ_1 relaxation rate, come from the Bloch-Redfield transversal contribution, while $f_z = e^{-\chi(t)}$ is the pure dephasing factor containing the pure dephasing rate Γ_2^* and originates from the longitudinal contribution only. If the Hamiltonian can be written as $H = H_0 + V(t)$, with V(t) containing the noise fluctuations in its parallel $V_z(t)$ and transverse $V_{\perp}(t)$ components, a perturbative expansion of the Liouville equation $\partial_t \tilde{\rho}(t) = -(i/\hbar)[V(t), \rho(t)]$ can be applied (see Appendix E). Within the assumption of weak, stationary, and averaged-to-zero noise, the expressions for Γ_1 and $\chi(t)$ are given by

$$\Gamma_1 = \frac{2}{\hbar^2} \int_0^\infty d\tau \, \langle V_\perp(0) V_\perp(\tau) \rangle \cos[E_{01}\tau/\hbar], \quad (21)$$

$$\chi(t) = \frac{4}{\hbar^2} \int_0^t dt'' \int_0^{t''} dt' \left\langle V_z(t'') V_z(t') \right\rangle, \qquad (22)$$

with $\chi(t)$ dependent on the noise statistics and spectrum. In fact, once $V_{\perp}(t)$ and $V_{z}(t)$ are expressed in terms of δn_{g} , it can be seen that the decoherence rates are related to the autocorrelation of the noise $C_{\delta n_g}(\tau) = \langle \delta n_g(0) \delta n_g(\tau) \rangle$ and thus to its PSD $S_{\delta n_g}(\omega) = (1/2\pi) \int_{-\infty}^{+\infty} C_{\delta n_g}(\tau) e^{i\omega\tau} d\tau$. In particular, Γ_1 contains the value of $S_{\delta n_g}(\omega)$ at the resonant frequency of the system E_{01}/\hbar , while the form of $\chi(t)$ depends both on the expression of the PSD and the position of its cutoff frequencies ω_{IR} and ω_{UV} with respect to the evolution time [74]. Here we use a wide-band noise approximation, which assumes a noise bandwidth wide enough that the inverse of the dephasing time T_2^* falls between the noise cutoffs, i.e., $\omega_{\rm IR} \leq 2\pi/T_2^* \ll \omega_{\rm UV}$. The choice of this assumption can be verified self consistently, once the values of the dephasing times are determined. Since 1/f noise has been detected at frequencies $f \gg$ 1 MHz, as far as we obtain values of T_2^* such that $T_2^* \gtrsim$ 1 μ s, we can consider the wide-band assumption valid. An extensive description and derivation of the equations used in this section can be found in Appendix E.

A. Free evolution

Specifically to our system, for the nondriven case, we can derive the relaxation and dephasing rates Γ_1 and Γ_2^* by perturbatively expanding the Hamiltonian expressed in the diagonal basis of instantaneous eigenstates, Eq. (4). At first leading orders of the noise contribution, the Hamiltonian is

given by

Ì

$$H_{I}[n_{g} + \delta n_{g}(t)] \simeq -\sqrt{E_{M}^{2} + t_{0}^{2} \cos^{2}(2\pi n_{g})}\sigma_{z} + \frac{\pi t_{0}^{2} \sin(4\pi n_{g})}{\sqrt{E_{M}^{2} + t_{0}^{2} \cos^{2}(2\pi n_{g})}}\delta n_{g}\sigma_{z} - \frac{hE_{M}t_{0} \sin(2\pi n_{g})}{2[E_{M}^{2} + t_{0}^{2} \cos^{2}(2\pi n_{g})]}(\delta n_{g})'\sigma_{y} + O(\delta n_{g}^{2}),$$
(23)

which is in the form $H(t) = H_0\sigma_z + V_z\delta n_g\sigma_z + V_y(\delta n_g)'\sigma_y$, with $V_z \equiv \partial H_0/\partial n_g$, and unusually contains the derivative of the noise in the σ_y term instead of a first-order term in δn_g . This term comes from the nonadiabatic transitions' contribution due to the fact that the noise affects the instantaneous eigenstates of the system over time. Here we therefore assume that the noise modulation is a differentiable function, and that $\partial_t n_g(t)$ can be uniquely defined. From Eq. (21), the expression of the relaxation rate can be obtained as

$$\Gamma_{1}^{(1)} \simeq \frac{2}{\hbar^{2}} |V_{y}|^{2} \int_{0}^{+\infty} d\tau \, \langle (\delta n_{g})'(0) (\delta n_{g})'(\tau) \rangle \, e^{-i\omega_{01}\tau}$$
$$= \frac{4\pi}{\hbar^{2}} |V_{y}|^{2} S_{(\delta n_{g})'}(f_{01}). \tag{24}$$

From the Fourier transform properties, if the PSD of the noise variable δn_g is $S_{\delta n_g}(\omega) = \alpha/\omega$, $\omega_{\rm IR} < \omega < \omega_{\rm UV}$, we have $S_{(\delta n_g)'}(\omega) = \omega^2 S_{\delta n_g}(\omega) = \alpha \omega$. Knowing that $\omega_{01} = 2\pi f_{01} = 2\pi \cdot 2\sqrt{E_M^2 + t_0^2 \cos^2(2\pi n_g)}$, the decoherence rate Γ_1 is given by

$$\Gamma_{1}^{(1)} \simeq 2(2\pi)^{3} \left(\frac{(E_{M}t_{0}\sin(2\pi n_{g}))^{2}}{4(E_{M}^{2} + t_{0}^{2}\cos^{2}(2\pi n_{g}))^{2}} \right) 2\pi f_{01}\alpha$$

= $\alpha (2\pi)^{4} \frac{E_{M}^{2}t_{0}^{2}\sin^{2}(2\pi n_{g})}{[E_{M}^{2} + t_{0}^{2}\cos^{2}(2\pi n_{g})]^{3/2}}.$ (25)

For the calculation of the pure dephasing, under the assumption of wide-band 1/f noise, the modulus of the dephasing factor $|f_z|$ takes the form of an almost-Gaussian decay function at leading order in $1/\omega_{\text{IR}}t$ (see Appendix E

$$|f_z| \simeq e^{-(4/\hbar^2)|V_z|^2 \alpha \ln[2\pi/(\omega_{\rm IR} t)]t^2},$$
(26)

from which we obtain the following condition for the pure dephasing time $T_2^* \equiv 1/\Gamma_2^*$:

$$\left(\frac{4\pi^2 t_0^2 \sin(4\pi n_g)}{\sqrt{E_M^2 + t_0^2 \cos^2(2\pi n_g)}}\right)^2 \alpha \ln\left(\frac{1}{f_{\rm IR}T_2^*}\right) (T_2^*)^2 = 1.$$
(27)

B. Analysis near sweet spots

From Eq. (23), it can be seen that both the coefficients $|V_v|$ and $|V_z|$ of the Hamiltonian vanish at $n_g = 0$, with $|V_z|$ also vanishing at $n_g = 1/4$. To determine the decoherence effects at these sweet spots, the next leading order terms in the Hamiltonian expansion have to be taken into account. With regards to Γ_1 , this term is given by $V_y^{(2)} \delta n_g (\delta n_g)'$, with $V_y^{(2)} \equiv \partial V_y / \partial n_g$. It should be noted that the variable representing the transverse noise contribution at this point, $\delta n_{\sigma} (\delta n_{\sigma})'$, is generally not Gaussian. However, it can be shown that its spectrum is regular at $\omega = 0$, so that the Bloch-Redfield approach used for the first-order contribution still applies. For a stochastic stationary process x(t), we have, from the properties of the Fourier transform, $S_{x x'}(\omega) = (\omega^2/4)S_{x^2}(\omega)$. Hence we can determine the power spectral density for $\delta n_g (\delta n_g)'$ from the expression of $S_{\delta n_\sigma^2}$, as follows. Knowing that, for two jointly Gaussian variables x and y, we have $\langle x^2 y^2 \rangle = \langle x^2 \rangle \langle y^2 \rangle + 2 \langle xy \rangle^2$, we can approximate $\langle \delta n_g(0)^2 \delta n_g(\tau)^2 \rangle \sim 2 \langle \delta n_g(0) \delta n_g(\tau) \rangle^2$ so that $S_{\delta n_g^2}(\omega)$ is given by $S_{\delta n_{\alpha}^2}(\omega) \sim (1/\pi) \int_{-\infty}^{+\infty} \{C_{\delta n_g}(\tau)\}^2 e^{i\omega\tau} d\tau \sim$ $8\alpha^2 \ln |\omega/\omega_{\rm IR}|/|\omega|$ for $\omega_{\rm IR} \ll \omega \ll \omega_{\rm UV}$. We can see that the power spectral density for $\delta n_g (\delta n_g)'$ follows a quasilinear law $S_{\partial_t(\delta n_{\sigma}^2)/2}(\omega) \sim |\omega| \ln |\omega|$.

Because of the regularity of the spectrum at $\omega \sim 0$ and the short correlation time, we can assume that the results obtained from perturbation theory in Eq. (21) are still applicable for the relaxation at the optimal point $n_g = 0$ [83]. In this way, the second-order correction to the relaxation produces an exponential decay with relaxation rate given by

$$\Gamma_{1}^{(2)} = \frac{4\pi}{\hbar^{2}} |V_{y}^{(2)}|^{2} S_{\delta n_{g}(\delta n_{g})'}(f_{01})$$

$$\sim \frac{8\pi\alpha^{2}}{\hbar^{2}} |V_{y}^{(2)}|^{2} (2\pi f_{01}) \ln |f_{01}/f_{\mathrm{IR}}| \qquad (28)$$

with $f_{01} = 2\sqrt{E_M^2 + t_0^2 \cos^2(2\pi n_g)}$. With regards to Γ_2^* , the next leading term in the Hamiltonian expansion is $\frac{1}{2}V_z^{(2)}(\delta n_g)^2$, with $V_z^{(2)} \equiv \partial^2 H_0/\partial n_g^2$. Because of the long correlation time of $(\delta n_g)^2$, the Gaussian approximation and

perturbation theory are no longer valid for the determination of the pure dephasing effects at the optimal point. Instead, the Keldysh diagrams' method gives the following dynamics for the dephasing factor f_z [82] at long times:

$$|f_z(t)| = \exp\left\{-\frac{t}{2}\int_{2\pi/t}^{+\infty} \ln\left(1 + \frac{4|V_z^{(2)}|^2}{\hbar^2}(S_{\delta n_g}(\omega))^2\right)d\omega\right\}.$$
(29)

For $S_{\delta n_g}(\omega) = \alpha/\omega$ and $t \gg t_c$, with $t_c \equiv 1/(2|V_z^{(2)}|\alpha)$, this expression leads to an exponential decay, with dephasing rate given by

$$\Gamma_2^{*(2)} \sim -\frac{\pi}{\hbar} |V_z^{(2)}| \alpha.$$
 (30)

Figures 4(a) and 4(b) respectively show the elements of the Hamiltonian expansion contributing to the decoherence effects, and the derived relaxation and dephasing times T_1 and T_2 , with $T_1 \equiv 1/\Gamma_1$ and T_2 obtained by setting $\exp\{-\Gamma_1 T_2/2\}f_z(T_2) = 1/e$. The second-order corrections at the sweet spot are restricted to a very narrow range of n_g , and thus we neglect the contributions coming from crosscorrelations and approximate $\Gamma_1\simeq \Gamma_1^{(1)}+ \Gamma_1^{(2)}$ and $\Gamma_2^*\simeq$ $\Gamma_2^{*(1)} + \Gamma_2^{*(2)}$. The two times are plotted against the value of the parameter n_g and the value of the noise strength at the sweet spot $n_g = 0$. The other parameters' values are the optimized quantities that can be used for implementing an X-gate operation. The noise is assumed to have $\omega_{\rm IR} = 10$ Hz, which coincides with the value we use for the numerical simulation of the driven, noisy evolution described in the next section. Even if lower noise cutoffs have been reported in the literature, with values down to $\omega_{\rm IR} \sim 0.1$ Hz, we can see from (26) that the dependence



FIG. 4. Effect of the 1/f charge noise on the Majorana transmon qubit's free evolution. (a) Contributing elements at the first two leading orders in the expansion of the Hamiltonian with respect to the noise δn_g ; see Eq. (23). (b) Decoherence and dephasing times for the Majorana transmon qubit as a function of the noise strength $\alpha \in [10^{-6}, 10^{-7}]$ at $n_g = 0$ (left side of the graph) and as a function of $n_g \in [0, 1/4]$ for $\alpha = 10^{-7}$ (right side of the graph). For all plots, $E_C/h = 0.4$ GHz, $E_J = 10E_C$, and $E_M = 0.012E_C$. Two sweet spots can be noticed here, with $n_g = 0$ being a sweet spot for both the relaxation and the dephasing effects.

of the dephasing factor on ω_{IR} is only logarithmic, and thus the choice of this higher value of noise cutoff carries an error that is not significant for our analysis. From Fig. 4(b), it can be seen that the values of the relaxation and the dephasing differ by several orders of magnitude for most of the range of n_g . This is due to the fact that the protocol is implemented in the basis of the eigenstates of the system, and the projection positively affects the relaxation, leaving only the contributions coming from nonadiabatic transitions between the instantaneous eigenstates. In particular, we can see that the dephasing time at the sweet spot ranges from 1.4 to 14 ms, values that are larger than the dephasing times of the current state-of-the-art superconducting qubits [4,85]. For a quantitative comparison, we can derive the relaxation and coherence times in the case of a regular transmon without the presence of the Majorana zero modes, and subjected to the same level of noise. The relaxation rate in this case can be obtained using the formula equivalent to Fermi's golden rule [4,86], $\Gamma_1 =$ $(1/\hbar^2) \left| \langle \Psi_0 | \partial H_q / \partial n_g | \Psi_1 \rangle \right|^2 S_{\delta n_g}(\omega_{01}), \text{ where } \{ | \Psi_0 \rangle, | \Psi_1 \rangle \}$ are the transmon qubit states and $\partial H_q/\partial n_g$ is the qubit susceptibility. The latter can be obtained from the expansion up to the first order in the noise fluctuation δn_{g} of the transmon Hamiltonian $4E_C(n-n_g)^2 - E_J \cos(\varphi)$ and yields $\partial H_q / \partial n_g \sim 8 E_C n$. The charge operator n has nonzero offdiagonal elements in the transmon qubit subspace. Therefore, under the harmonic approximation, we obtain [3] $\langle \Psi_0 | (\partial H / \partial n_g) | \Psi_1 \rangle \simeq 8 E_C (E_J / 8 E_C)^{1/4} / \sqrt{2}$. This quantity increases with E_J/E_C , and for parameters $E_C = 0.4$ GHz, $E_J/E_C = 10$ and for a 1/f noise with noise strength $\alpha = 10^{-7}$, it leads to a relaxation time of $T_1 = 1/\Gamma_1 \sim$ 0.3 ms. Under the same harmonic approximation, this method leads to an infinite relaxation time for the Majorana transmon, since the MT intradoublet coupling $\langle \Psi^+ | \hat{n} | \Psi^- \rangle$ vanishes [49,50]. If we compare the value of T_1 obtained for a regular transmon with the values shown in Fig. 4, we can see that the involvement of the Majorana modes improves the relaxation times by an order of magnitude ranging from 10^2 to 10^6 at the sweet spot $n_g = 0$. We can also see an improvement in the dephasing time. The same approach outlined above for the description of the dephasing under free evolution can be applied to a regular transmon, with the difference that in the latter case the energy terms contributing to the dephasing, V_z and $V_z^{(2)}$, are proportional to the transmon energy splitting of about $t_1 - t_0$. The Majorana transmon model has a much smaller qubit splitting, $\sqrt{E_M^2 + t_0^2 \cos^2(2\pi n_g)} \sim t_0$, that leads to much smaller values of V_z and $V_z^{(2)}$, dictating the strength of the dephasing rate $1/T_2^*$ in Eqs. (27) and (30). This means that, for the same values of the system and noise parameters, the coherence of the qubit is improved by a factor of $t_1/t_0 = 2^4 (E_J/2E_C)^{1/2}$. Quantitatively, in the case of a transmon qubit with $E_C = 0.4$ GHz, $E_J/E_C = 10$, and a 1/f noise with noise strength $\alpha = 10^{-7}$ and infrared cutoff $f_{IR} = 10$ Hz, the pure dephasing time ranges from $T_2^* \sim 0.3 \ \mu s$ at $n_g = 1/4$, to $T_2^* \sim 0.15$ ms at the sweet spot $n_g = 0$. Compared to the Majorana transmon's coherence times shown in Fig. 4, the improvement due to the presence of the MZMs is 2 orders of magnitude.

C. Driven evolution

For the driven evolution, because of the nonlinearity of the driving term used for the gate protocol, the effects of the 1/f noise fluctuations $\delta n_g(t)$ are studied numerically, simulating the evolution of the density operator $\rho(t)$ using a time-noise series $\{\tilde{n}_g(t_i)\}$, with $\tilde{n}_g(t_i) =$ $n_{g}(t_{i}) + \delta n_{g}(t_{i})$, and averaging over 10⁴ noise trajectories. To obtain a good approximation of the time evolution operator $U_I(t_N) = \prod_{j=0}^{N-1} U_I(t_{j+1}, t_j)$, with $U_I(t_{j+1}, t_j) = \exp\{-iH_I(t_{j+1})dt/\hbar\}$, we simulate a stepwise constant time series for $\delta n_{\sigma}(t_i)$, with noise jumps dependent on the chosen spectral characteristics, $dt_J = 1/2f_{\rm UV}$, with $f_{\rm UV}$ being the high cutoff frequency for the noise PSD, and a smaller evolution time step dt = 1 ns. The values of the fluctuations at each jump are calculated through a Gaussian white noise filtering in a chosen frequency range $f \in$ $[f_{\rm IR}, f_{\rm UV}]$. To generalize the white noise filtering including a random phase of the variable's Fourier transform, a series of complex numbers for the frequency space $\tilde{x}_k = (1/\sqrt{2})(\tilde{x}_{k,1} + i\tilde{x}_{k,2})$ is generated, with $\tilde{x}_{k,1}$ and $\tilde{x}_{k,2}$ zero-average Gaussian white noise sequences with unit variance, with sampling range chosen such that the correspondent time-series step is the dt_J defined above and the final time is $T_J \ge 1/f_{\rm IR}$. The series is then filtered in the frequency space, $\tilde{y}_k = |H(f_k)|\tilde{x}_k$, using a filter amplitude of $|H(f_k)| = \sqrt{S(f_k)\delta f}/2$, with $S(f_k)$ the sampled PSD defined for positive frequencies, $f_k = k\delta f$, and $\delta f = 1/T_J$. Both \tilde{x}_k and $|H(f_k)|$ are constructed in such a way that we obtain a real Fourier series for the variable \tilde{y}_k . The resulting 1/f noise time-series variables used for the simulation are given by $\delta n_g(t_j) = \sum_k \tilde{y}_k e^{-i2\pi jk/N}$. The gate fidelity used for optimizing the protocol is not suitable in this case, because the evolution is no longer unitary when averaged over the noise trajectories. We need to use the more generic Uhlmann fidelity [87] between density operators, averaged over the Hilbert space. Luckily, the average over noise trajectories of the time-evolution operator act as a linear, trace-preserving transformation, $\mathcal{M}[\rho(t_N)] =$ $\langle U_I(t_N)\rho(0)U_I^{\dagger}(t_N)\rangle_{\text{trai}}$. Hence, a simplified expression for the average fidelity can be used [88]:

$$\bar{\mathcal{F}}_G = \frac{1}{6} \sum_{j=\pm x, \pm y, \pm z} \operatorname{Tr}(G\rho_j G^{\dagger} \mathcal{M}[\rho_j]).$$
(31)

Here G is the target unitary gate and ρ_j represents each of the eigenstates of the Pauli operator σ_j . In fact, this expression allows us to determine $\bar{\mathcal{F}}_G$ by averaging between only some specific points in the Bloch sphere.



FIG. 5. Effect of the 1/f charge noise $\delta n_g(t)$ on the X gate protocol with $t_F = 4T$ and stability against variations of other parameters. (a) Single time-series trajectory of the simulated $\delta n_g(t)$ and related periodogram. The noise has been simulated via white noise filtering, with noise strength $\alpha \sim 10^{-6}$, frequency window 10 Hz–50 MHz, and a time step for the stepwise constant series $\delta n_g(t_n)$ of $\delta t = 1$ ns. In the right panel, the gray curve indicates the noise jumps' periodogram while the blue curve represents the periodogram of the stepwise constant time series. (b) Fidelity of the protocol taking into account systematic error on $n_g(0)$, without charge noise (solid blue line) and with charge noise added (dash-dot blue line). The Gaussian distribution of the noise acting on the parameter is sketched in the background, with values of σ_{n_g} and $3\sigma_{n_g}$ ($\sigma_{n_g} \sim 10^{-3}$, assuming Gaussian 1/f noise). Inset: fidelity of the noise-free protocol varying $n_g(0)$ from 0 to 0.5, showing that the protocol is quite stable near $n_g \sim 0$. Also, it can be noted that \mathcal{F}_X does not change for jumps $n_g \rightarrow n_g + 1/2$. (c),(d) Fidelity of the protocol taking into account a systematic error on E_J and E_M , without charge noise (solid blue line) and with charge noise added (dotted blue line). The parameters used at zero noise level are $E_C/h = 0.4$ GHz, $E_J = 10E_C$, $E_M = 0.012E_C$, and T = 189.3 ns.

Figure 5 shows the results of the simulation for the Xgate protocol, with the parameters of Table I and a total evolution time of $T_G \sim 200$ ns. The noise has been produced with a PSD taking the form $S(f) = \alpha/f$ for frequencies 10 Hz < f < 50 MHz, and having a flat contribution S(f) = S(10 Hz) at lower frequencies $f \leq 10 \text{ Hz}$. We also set $\alpha = 10^{-6}$. The use of the Fourier transform constrains us to the choice of a limited noise bandwidth. The bandwidth above, [10 Hz, 50 MHz], has been chosen to ensure the inclusion of the resonant frequency of the system, of the order of $\omega_R \sim 10$ MHz. The absence of the higher cutoff in the dephasing factor (27) can indicate that the short-time (large frequency $f \gg 1/T_G$) noise contributions are not involved in the averaged evolution (this is a consequence of both the weak coupling between the system and the noise source and the 1/f behavior of the PSD), and thus our choice of the higher cutoff above is based on the condition $f_{\rm UV} \gg 1/T_G \sim 5$ MHz. The chosen lower cutoff f_{IR} is the minimum value that we can use to ensure a high value of $f_{\rm UV}$ in the numerical simulation. Even if the actual f_{IR} can be lower, we can assume that the chosen value carries only a logarithmic error on the dynamics, like in the free evolution case. In the figure, one of the stepwise constant $\delta n_{g}(t_{i})$ trajectories is plotted in the upper panel [Fig. 5(a)], along with its periodogram. In Figs. 5(b)-5(d) the average fidelities with respect to fluctuations of the variables $n_g(t=0), E_J$, and E_M are determined. The protocol turns out to be particularly insensitive to fluctuations of $n_g(0)$, with a fidelity reduction of about 0.02% at $3\sigma_{n_g}$ for the combined effect of systematic and 1/f noise. Good results also seem to be achieved in the case of fluctuations on the other two parameters. In fact, to have a fidelity drop of the about 0.2%, a systematic error of 1.5% on E_J and 2% on E_M is needed.

V. CONCLUSIONS

In this work we investigated the possibility of controlling the Majorana transmon gubit, defined as the lowest doublet of the Majorana transmon [49,50] energy spectrum, exploiting a voltage-gate modulation of the induced offset charge $n_{g}(t)$. We modeled this dynamical modulation as a sinusoidal function such that it periodically passes through the avoided crossing point $n_g = 1/4$, introducing a nonlinear driving term in the Hamiltonian, and worked in the basis of the instantaneous eigenstates of the system. Because of the high anharmonicity present in the system at $E_J \gg E_C \gg E_M$, we assumed the dynamics to be restricted to the lowest doublet of the spectrum. We analyzed the projected Hamiltonian using the counter-rotating hybridized rotating-wave method [65] and we demonstrated that the effective evolution at an integer number of oscillations results in a combination of x and z rotations whose coefficients can be tuned using the internal and external parameters of the Hamiltonian. We then proposed two different protocols for the control of the qubit, one in

the laboratory frame and the other in the rotating frame of the qubit frequency, with the first one having the advantage of faster operations and the absence of internal parameter switching, and the second one being slower but without the need of precise timing during idle times. Both the methods provide a set of single-qubit gates with control error lower than about 2×10^{-4} when calculated at the zero noise level. This error is related to the limitation of the control to a simple sinusoidal function and can potentially be reduced using optimal control techniques. We also studied the effect of 1/f additive noise to the parameter $n_{\sigma}(t)$, assuming the coupling to the noise source to be weak, and the fluctuations Gaussian, stationary, and averaged to zero. We applied a perturbative analysis to the Liouville equation and obtained an analytical expression for the relaxation and the dephasing rates under free evolution. From the calculations, the system presents a sweet spot at $n_{\sigma} = 0$ common to both decoherence effects. The dephasing mechanism is the one mainly affecting the system in the whole range of $n_g \in [0, 0.5]$, and leads to dephasing times $T_{\phi} \sim$ 1.4 - 14 ms at the sweet spot, for noise strength in the range $\alpha \in [10^{-6}, 10^{-7}]$. These values for T_{ϕ} are typically beyond the current state-of-the-art transmon [4,89]. For the driven evolution, we performed a numerical simulation of the effects of the additive noise, modeling $\delta n_{\sigma}(t)$ as a stepwise constant signal with jumps produced through white noise filtering. We compared the noise-free and noisy average fidelities of the X gate to derive a quantitative effect of the simulated 1/f noise, finding a noise-related reduction smaller than 0.01%. Finally, we looked at the average fidelity reduction due to systematic errors in the different parameters of the system and found low sensitivity to systematic error in the initial value of n_g , $n_g(0)$, and on the parameters E_M and E_J .

ACKNOWLEDGMENTS

The authors acknowledge support from the European Commission's Horizon 2020 research and innovation programme under Grant Agreement No. 766714/HiTIMe. E.L. and E.Gi. gratefully thank Dr. Elinor Irish for the useful discussion about the Hamiltonian treatment and M. Stern for the useful discussion about the experimental implementation. E.Gr. acknowledges support from the Israel Science Foundation under Grant No. 1626/16.

APPENDIX A: THEORETICAL DESCRIPTION OF THE MAJORANA TRANSMON

In this appendix we review the Majorana transmon system, which has been introduced in Ref. [49] and applied or analyzed further in a few other works [30,50,54,61]. We present an overview of the model for completeness of the discussion and to quantitatively support the harmonic approximation applied to the projected Hamiltonian in the lowest doublet of the spectrum, used throughout the paper. We specifically consider the model originally introduced, which describes the low-energy physics of the hybrid system in the topological phase. As described in Sec. II, the superconducting part of the hybrid qubit consists of a traditional Cooper pair box. Its Hamiltonian, in the basis of the relative superconducting phase $\varphi = \varphi_L - \varphi_R$ between the left *L* and right *R* junction leads is given by

$$H_T[n_g] = 4E_c(-i\partial_{\varphi} - n_g)^2 - E_J \cos{(\varphi)}, \qquad (A1)$$

where $-i\partial_{\varphi} = \hat{n} = \frac{1}{2}(n_L - n_R)$ represents the relative number of Cooper pairs, with n_L (n_R) being the Cooper pair number of the left (right) lead. The eigenfunctions $\langle \varphi | \Psi_k \rangle = \Psi_k(\varphi)$ of $H_T[n_{\varphi}]$ are combinations of Mathieu functions [89] with boundary conditions set by the parity of the charge n, which is even in absence of the spare electrons, i.e., the wavefunctions have symmetric boundary conditions $\Psi_k(\varphi + 2\pi) = \Psi_k(\varphi)$. When the nanowire is placed on top of the leads, the superconducting proximity effect helps the formation of the topological phase in correspondence of the two sections of the junction, and the formation of the four Majorana zero modes at their edges. With the Majorana quasiparticles being at zero energy, this setup is not sufficient to make them appear in the Hamiltonian. The Majorana transmon model takes into account an additional interaction energy term between the neighboring MZMs near the tunnel junction, originating from a partial overlap. This term can be modeled with a tunneling Hamiltonian of the form

$$H_M = iE_M \cos{(\varphi/2)\gamma_2\gamma_3}, \qquad (A2)$$

where γ_2 and γ_3 are the creation operators of the neighboring Majorana quasiparticles, and E_M represents the coupling energy. In terms of the electron occupation number, H_M connects states of different relative parities, thus hybridizing the states of the superconducting system. To see this, we indicate with $N_{L,R} = 2n_{L,R} [\text{mod}2]$ the occupation of the delocalized fermions $c_{L,R} = (1/\sqrt{2})(\gamma_{1,3} + i\gamma_{2,4})$ in each nanowire, and identify the two subspaces of even and odd relative parity as [49]

$$\{ e^{i\varphi n} | N_L, N_R \rangle : N_L, N_R = 0, 1 \land n \in \mathbb{Z} \},$$

$$\{ e^{i\varphi n} | N_L, N_R \rangle : N_L, N_R = 0, 1 \land n \in \mathbb{Z} + \frac{1}{2} \}.$$
(A3)

Thus, the interaction term (A2) written in terms of $c_{L,R}$ and $c_{L,R}^{\dagger}$ allows the transitions

$$e^{i\varphi n} |N_L, N_R\rangle \leftrightarrow e^{i\varphi(n\pm 1/2)} |1 - N_L, 1 - N_R\rangle.$$
 (A4)

The relative even and odd parity degrees of freedom can be described by a two-component vector. In this way the Hamiltonian of the combined system $H_{MT} = H_T + H_M$ can be written in the form

$$H_{MT} = \begin{pmatrix} H_T[n_g] & E_M \cos(\varphi/2) \\ E_M \cos(\varphi/2) & H_T[n_g] \end{pmatrix}, \quad (A5)$$

which is the low-energy effective Hamiltonian presented in Ref. [49]. The delocalized fermions of the nanowires can introduce spare electrons in the system, and hence the kth eigenfunction of H_T in each parity subspace is represented by $\langle \varphi | \Psi_k^e \rangle = (\Psi_k^e(\varphi), 0)^T$ and $\langle \varphi | \Psi_k^o \rangle =$ $[0, \Psi_k^o(\varphi)]^T$, with $\Psi_k^{e,o}(\varphi)$ the solution of $H_T[n_g]$ with symmetric and antisymmetric periodic boundary conditions, respectively [50]. The hybridization due to H_M produces a doublet structure of the spectrum of the combined system. This is visible even with a low value of the ratio E_I/E_C (see Fig. 6). We can thus conveniently label the eigenstates of the full Hamiltonian with $|\Psi_i^{\pm}\rangle$, where j is the energy band and the \pm sign is related to the split levels within the band (this notation becomes even more useful when working in the transmon regime). Hence, a generic solution of Eq. (A5) can be expressed as $|\Psi_i^{\pm}\rangle = \sum_k (\alpha_k^j |\Psi_k^e\rangle +$ $\beta_k^j | \Psi_k^o \rangle$), with α_k^j and β_k^j parametrically dependent on the other variables.

We are interested in the limit of high Josephson energy $E_J \gg E_C$ (transmon regime). To see the effect that the interaction term H_M has on the system, the energy spectrum is plotted in Fig. 6(a). Even with a low value of $E_J/E_C = 3$ (charging regime), the doublet structure introduced by E_M is visible. On the one hand, going towards $E_J/E_C \gg 1$ increases the anharmonicity already present at lower values, but on the other, it "flattens" the energy bands. Instead, the value of the interaction energy E_M is useful in changing the energy dispersion $\epsilon_k = |E_{k,\pm}(0) - E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{k,\pm}(0)|E_{$ $E_{k+}(1/4)$ [see Fig. 6(a), right panel] without affecting the anharmonicity. Figure 6(b) shows the matrix elements of the interaction Hamiltonian (A2) connecting the transmon eigenstates of different parities, in units of E_M . Apart from a linear proportionality with respect to E_M , the interaction between transmon wavefunctions that belongs to different energy bands tends to zero as the superconducting qubit goes into the transmon regime. In fact, the Hamiltonian $H_T[n_g]$ in the limit of $E_J/E_C \gg 1$ resembles an anharmonic oscillator, and at zeroth order in $\sqrt{E_J/E_C}$ its eigenfunctions can be approximated by the harmonic oscillator wavefunctions. In this case, the overlap $\langle \Psi_k^e | H_M | \Psi_l^o \rangle$ can be shown to yield a polynomial decrease for |k - l|even, vanishing for |k - l| odd, while being constant for k = l [50]. This is even more evident when we look at the contribution of the transmon eigenstates $|\Psi_{k}^{e/o}\rangle$ to the linear superposition representing the eigenstates of the full Hamiltonian H_{MT} in Fig. 7. It can be seen that the hybridization due to H_M happens within each transmon band for $E_J/E_C \gtrsim 5$. Since in this work the control of the



FIG. 6. (a) The energy spectrum of the Majorana transmon system. Left: energy spectrum $E_{k,\pm}(n_g)$ as a function of n_g for the first four energy levels, for $E_C/h = 0.4$ GHz, $E_J/E_C = 3$, and $E_M/E_C = 0.1$. Even if it is not in the transmon regime, because of the Majorana interaction energy $E_M \ll E_C$, the spectrum presents a doubletlike spectrum with high anharmonicity. Right: energy dispersion $\epsilon_k = |E_{k,\pm}(0) - E_{k,\pm}(1/4)|$ for k = 0, 1 as a function of E_J/E_C , for different values of E_M/E_C : 0.12 (solid lines), 0.012 (dashed lines), 0.0012 (dotted lines). (b) Matrix elements of the interaction Hamiltonian H_M (A2) originating from the overlap of the neighboring Majorana zero modes near the Josephson junction and connecting transmon states of different relative fermion parities, in particular connecting the ground state (left) and the first excited state (right) of one of the parity sectors to the other eigenstates $\langle \Psi_{0/1}^e | H_M | \Psi_k^o \rangle$. The calculation is done in units of E_M , for different values of E_J/E_C : 0.5 (solid line), 5 (dashed line), 10 (dotted line), 25 (dash-dot line). For all calculations, $E_C/h = 0.4$ GHz.

qubit is done within the doublet with k = 0, it is reasonable to apply the harmonic approximation and neglect the interaction terms between different doublets. Regarding the diagonalization of $H_T[n_g]$, instead of approximating it to an anharmonic oscillator with a quartic term, we decide to use the transmon energy dispersion $\epsilon_k^T = \epsilon_k^{h.o.} \pm t_k \cos(2\pi n_g)$ derived from a WKB treatment [3], with $\epsilon_k^{h.o.}$ representing the *k*th eigenenergy of the harmonic oscillator with frequency $\sqrt{E_C E_J}$ and

$$t_k \equiv (-1)^{k+1} 2^{4(k+1)} \frac{E_C}{k!} \sqrt{\frac{2}{\pi}} \left(\frac{E_J}{2E_C}\right)^{k/2+3/4} e^{-\sqrt{8E_J/E_C}}.$$

The Hamiltonian assumes the block-diagonal form (1) presented in Sec. II:

$$H^{(k)} = \begin{pmatrix} \epsilon_k^{h.o.} + t_k \cos\left(2\pi n_g\right) & E_M \\ E_M & \epsilon_k^{h.o.} - t_k \cos\left(2\pi n_g\right) \end{pmatrix}.$$
(A6)



FIG. 7. Superposition of the eigenstates of the Majorana transmon with the uncoupled transmon states, where each panel represents one of the first four eigenstates of the system: $|\Psi_0^-\rangle$, $|\Psi_0^+\rangle$, $|\Psi_1^+\rangle$, $|\Psi_1^-\rangle$. The different lines correspond to contributions from different transmon energy states of different parity sectors for $E_J/E_C = 0.5$ (solid line), 5 (dashed line), 10 (dotted line), 25 (dash-dot line). For all calculations, $E_M/h = E_C/h = 0.4$ GHz. It can be seen that, for not too high values of E_J , the contribution from different parity bands is suppressed.

Each block $H^{(k)}$ can be diagonalized with a rotation about the *y* axis, i.e.,

$$|\Psi_k^-\rangle = \cos\left(\eta_k\right) |\Psi_k^e\rangle + \sin\left(\eta_k\right) |\Psi_k^o\rangle, \qquad (A7a)$$

$$|\Psi_k^+\rangle = -\sin\left(\eta_k\right)|\Psi_k^e\rangle + \cos\left(\eta_k\right)|\Psi_k^o\rangle, \qquad (A7b)$$

$$E_{k,\pm} = \epsilon_k^{h.o.} \pm (-1)^k \sqrt{E_M^2 + t_k^2 \cos^2(2\pi n_g)}, \quad (A7c)$$

where $\pm 1 = s$ represents the rotated parity and $\eta_k = ((-1)^{k+1}/2)\operatorname{atan2}(E_M, (-1)^{k+1}t_k\cos(2\pi n_g))$ is the mixing angle. In this work we make use of these limit solutions, restricting the dynamics to the two-dimensional subspace of k = 0.

APPENDIX B: EXPERIMENTAL REALIZATION

In this appendix we aim to explore the experimental feasibility of the n_g modulation proposed for the single gate protocol. Throughout this study we use values of E_C and E_J that are realistic for superconducting circuit devices [4]. Arguably, small values of E_M can be achieved as discussed in Sec. II. Here we want to determine the physical requirements for a clean modulation of the gate voltage of the qubit. The signal needed for the protocol

$$n_g(t) = \begin{cases} (1 - \cos(\omega t))/4, & 0 \le t \le 2\pi n/\omega, \\ 0, & \text{otherwise,} \end{cases}$$
(B1)

can be seen as a pulse with a frequency bandwidth of about tens of megahertz. We can assume that, in an hypothetical experimental apparatus, it can be reproduced by an arbitrary waveform generator (AWG), whose effect on the signal is represented by a Gaussian filter. This kind of effect has also been taken into account in works on optimal control algorithms in superconducting circuit devices that use the transfer function formalism [90], assuming AWG's sampling rate of 1 gigasample/sec and a Gaussian filtering attenuation of 250 MHz at $-3 \, dB$, meaning that it can be represented by a Gaussian filter of 300 MHz width. Both the values of the sampling rate and the width of the Gaussian filter are high enough to ensure a smooth interpolation of the digitalized input, and a negligible filtering effect on the output signal. A further analysis can be done regarding the physical effect of the coaxial line that is usually used for sending the voltage signal to the qubit in a superconducting circuit setup. In particular, we can find conditions under which the impedance of the coaxial line does not alter the said voltage modulation. Considering that a transmission line has a typical characteristic (lossless) impedance Z_0 of 50 Ω , and the impedance of a capacitor in an ac circuit is $Z_C = 1/(i\omega C)$, where C is its capacitance and ω is the frequency of the ac field across it, to have minimal effects coming from Z_0 we need all the voltage drop across the transmission line contributing to the voltage difference of the capacitance used to couple the coaxial line to the qubit, $V_C \gg V_{coax}$. This translates to $|Z_C| \gg |Z_{\text{coax}}|$ and thus $C \ll 1/(\omega * 50 \Omega)$. Assuming that, geometrically, $C \sim \epsilon d$, with d the dimension of a square capacitor, and $\epsilon \sim 8.85 \times 10^{-10}$ F/m, it follows that, to neglect the voltage drop of the coaxial line and have an ac voltage modulation of about 10 MHz across the capacitor, the latter needs to have dimensions $d \ll 2 \times 10^3$ m, which is orders of magnitude larger than the typical size of a capacitor in a superconducting circuit (micrometers). These arguments thus show the feasibility of a modulation of type (B1) in a realistic scenario, and that effects of deformation that can come from the superconducting external apparatus can be considered irrelevant at the frequency values presented in this work.

APPENDIX C: SINGLE-QUBIT GATE FIDELITY EXPRESSIONS

In this appendix we present the expressions for different single-qubit gates when using the n_g -modulated protocol described in Sec. III A, working in both the laboratory and the qubit rotating frames. In particular, we present the analytical formulas for the time evolution operator in the two frames, finding exact conditions for obtaining the X and the Hadamard H gates in the laboratory frame and the Z and the $T_{\pi/8}$ gates in the rotating frame. We also show the optimization plots and the implementation on the Bloch



FIG. 8. Optimization graphs and Bloch sphere evolution for the X, Z, Hadamard H, and $(T_{\pi/8})^{\dagger}$ gates working in the rotating frame of the qubit. Note that the X gate includes $(\sqrt{X})^{\dagger}$ when performed halfway. Upper panels: optimization graphs representing the fidelity for the specified gate as a function of $2E_M/\omega$ and A/ω , with $A = 2|t_0|J_1(\pi/2)$. The calculation is done using the CHRW approximation. The blue dot indicates the optimal point for the specified gate. For comparison, the red dot indicates the optimal point used for the evolution in Fig. 2, i.e., for the X gate with protocol time $t_F = 4T$. In all the plots the white lines represent the resonances and antiresonances of the sinusoidal component of the fidelities: $\sin(2\pi n \cdot \Omega T) = 0, 1$ (dashed, solid lines) for \mathcal{F}_X and \mathcal{F}_H , $\sin(2\pi n \cdot \Omega T) = 1, 0$ (dashed, solid lines) for \mathcal{F}_Z and $\mathcal{F}_{(\pi/8)^{\dagger}}$. The black dotted lines represent the curves along which the gate can be optimized by only changing the frequency, keeping E_J and E_M fixed at the values optimized for the X gate. Lower panels: each gate is implemented on a specific state, using the optimal parameters indicated in the upper panels, and its evolution in the Bloch sphere is shown. The initial states are $(1/\sqrt{2})(|\Psi^+\rangle + |\Psi^-\rangle)$ for the Z and $(\pi/8)^{\dagger}$ gates, $|\Psi^-\rangle$ for the X and Hadamard H gates. For all panels, the charging and Josephson energies are $E_C/h = 0.4$ GHz and $E_J = 10E_C$.

sphere of some single-qubit gates in the qubit rotating frame (Fig. 8).

where we have

From Eq. (17), the evolution, in the laboratory frame, at an integer number of oscillations $t_F = 2nT$ is given by

$$U_I(2nT) \simeq (-1)^n R_v^{-1}[\eta_0] \tilde{U}_{\text{CHRW}}^{(\text{RF})}(2nT) R_v[\eta_0],$$

with $\tilde{U}_{\text{CHRW}}^{(\text{RF})}$ given by the time-evolution expression found using the CHRW method, Eq. (15) in Sec. III A, while $\eta_0 = \frac{1}{2} \operatorname{atan2}(E_M, |t_0|)$ is the mixing angle that diagonalizes the qubit Hamiltonian at the beginning and the end of the evolution, Eq. (3a). Knowing that $\cos(2\eta_0) \equiv$ $|t_0|/\sqrt{E_M^2 + |t_0|^2}$ and $\sin(2\eta_0) \equiv E_M/\sqrt{E_M^2 + |t_0|^2}$, we can explicitly write

$$U_{I}(2nT) \simeq \cos(n\Omega T)\mathbb{I} - i \frac{\sin(n\Omega T)}{\Omega\sqrt{E_{M}^{2} + |t_{0}|^{2}}} (c_{x}\sigma_{x} - c_{z}\sigma_{z}),$$
(C1)

$$\Omega = \sqrt{(\Delta - \omega)^2 + g^2/4},$$

$$c_z = |t_0|g/2 + (\Delta - \omega)E_M,$$

$$c_x = (\Delta - \omega)|t_0| - E_M g/2,$$

with the parameters given by

$$\Delta = 2E_M J_0(2A\kappa/\omega),$$

$$g = 8E_M J_1(2A\kappa/\omega),$$

$$\kappa = \text{Root}\{A(1-\kappa) - 2E_M J_1(2A\kappa/\omega)\},$$

$$A = 2|t_0|J_1(\pi/2).$$

In general, the optimal parameters for implementing a specific gate G can be determined numerically by maximizing the gate fidelity $\mathcal{F}_G = \frac{1}{4} |\text{Tr}(U_I^{\dagger}G)|^2$. However, it can be seen that, for the X and Hadamard gates, which are the ones of interest when working in the laboratory frame, the parameters can be optimized exactly, looking directly at Eq. (C1): for the X gate, the parameters' conditions are

$$c_z = 0$$
 and $n\Omega T = \pi/2 + m\pi$, with $m = 0, 1, \dots$; (C2a)

while for the Hadamard gate, we need

$$c_z = -c_x$$
 and $n\Omega T = \pi/2 + m\pi$, with $m = 0, 1, \dots$ (C2b)

As an alternative gate implementation, we also want to present the dynamics of the system obtained in the rotating frame of the qubit at t = 0. Passing to this rotating frame, the time evolution operator takes the form

$$U_{I}^{\text{RF}}(2nT) = e^{-in\Omega_{q}T\sigma_{z}}U_{I}(2nT) \simeq \cos(n\Omega_{q}T) \left\{ \cos(n\Omega T)\mathbb{I} - i\frac{\sin(n\Omega T)}{\Omega\sqrt{E_{M}^{2} + |t_{0}|^{2}}}(c_{x}\sigma_{x} - c_{z}\sigma_{z}) \right\}$$

+ $\sin(n\Omega_{q}T) \left\{ \frac{\sin(n\Omega T)}{\Omega\sqrt{E_{M}^{2} + |t_{0}|^{2}}} c_{z}\mathbb{I} - i\cos(n\Omega T)\sigma_{z} - i\frac{\sin(n\Omega T)}{\Omega\sqrt{E_{M}^{2} + |t_{0}|^{2}}} c_{x}\sigma_{y} \right\},$ (C3)

where we have $\Omega_q = 2\sqrt{t_0^2 + E_M^2}$. The optimization plots for the single-qubit gates X, Z, Hadamard H, and $(T_{\pi/8})^{\dagger}$ are shown in the upper panels of Fig. 8. The σ_z rotation of the rotating frame transformation introduces a σ_v term in the Hamiltonian, whose coefficient vanishes when one of the terms c_x , $\sin(n\Omega_q T)$, or $\sin(n\Omega T)$ do. Therefore, to obtain an X gate, we need $sin(n\Omega_q T) \sim 0$ and the same conditions as for the laboratory frame given in Eq. (C2a) to be fulfilled. The solutions in this case are not exact, but from the plot of the fidelity $\mathcal{F}_X^{\text{RF}}$ in Fig. 8, it can be seen that the optimized points in the area of the parameter space of interest are close to the same resonances of the laboratory frame. A similar argument can be made for the Hadamard gate, which requires both the σ_x and σ_z terms. Regarding the Z gate, we can identify some exact points, obtained for $\cos(n\Omega_q T) = 0$ and $\sin(n\Omega T) = 0$. The other optimized points presumably belong to the case of $sin(n\Omega_q T) = 0$, but do not have an exact solution and they are not of interest for this study. In the same way a subset of exact solutions can be found for the $(T_{\pi/8})^{\dagger}$ gate, with the conditions $sin(n\Omega T) = 0$ (white lines in Fig. 8) and $n\Omega_a T =$ $-\pi/8 + k\pi$ for $k \in \mathbb{N}$. Finally, the lower panels of Fig. 8 show the implementation of such gates on the Bloch sphere in the rotating frame.

APPENDIX D: ADIABATIC CONDITION'S ESTIMATE WHEN OPERATING IN THE ROTATING FRAME

In this appendix we present a realistic example of parameter switching needed when operating in the rotating frame to apply a simple sequence of single-qubit gates to the Majorana transmon qubit. In fact, when working in the rotating frame using the n_g -modulated protocol to implement single-qubit gates, before performing each gate operation the parameters of the system need to be tuned

to their optimized values, keeping $n_g = 0$. In Table II we show how the parameters optimization can be done by keeping E_J fixed, so that only ω and E_M need to be tuned when changing the qubit gate. Because E_M represents an internal parameter of the system, tuning its value can introduce nonadiabatic transitions between its eigenstates $|\Psi^-\rangle$ and $|\Psi^+\rangle$. Thus we need to derive the condition for having an adiabatic evolution during this operation. The switching between different values of E_M can be represented by a continuous function of time $E_M(t)$ and leads to a timedependent Hamiltonian that, in the basis $\{|\Psi^-\rangle, |\Psi^+\rangle\}$, presents the nonadiabatic σ_v term

$$H_{\text{Switch}} = \sqrt{t_0^2 + E_M^2(t)}\sigma_z + \frac{|t_0|\partial_t E_M(t)}{4\pi[t_0^2 + E_M^2(t)]}\sigma_y.$$
 (D1)

The adiabatic condition is derived by imposing that the σ_y term be negligible with respect to the diagonal σ_z term:

$$\max_{0 \le t \le \tau} \left| \frac{|t_0| \partial_t E_M(t)}{4\pi [t_0^2 + E_M^2(t)]^{3/2}} \right| \ll 1.$$
 (D2)

This is also equivalent to $\max |[\partial_t H(t)]_{mn}/(\Delta E_{mn})^2| \ll 1$. Condition (D2) also needs to be combined with the condition of obtaining an identity operation during the parameter's switch. To give some realistic estimates, we choose to analyze the case of the two-gate sequence XZ. This is an adequate case since only single-qubit gates within the chosen universal set are significant for quantum computing purposes, and we gave as an example in Sec. III B the set of gates $\{H, S, T\}$ and $\{X, Y, Z, T\}$. Given that Y = -iXZ, we can reduce each of these sets to the use of only one gate that performs a fixed rotation perpendicular to the z axis (either H or X) and two gates performing fixed rotations about the z axis. Thus, it is worth analyzing the case of a sequence of these two types of single-qubit gates. When we apply the XZ sequence in the rotating frame, in between these two operations we need to tune the parameter E_M from E_M^X to E_M^Z , optimized values for the X and Z gates, respectively. The function we choose for the smooth switch is the sinusoidal function

$$E_M(t) = E_M^X + \frac{E_M^Z - E_M^X}{2} (1 - \cos(\pi t/\tau))$$
(D3)

with τ the time of the switching operation. When calculating the condition for τ for fulfilling the adiabatic criterion (D2), using the values of E_M^X , E_M^Z , and t_0 from Table II, we obtain $\tau \gg 10$ ns. Regarding the condition for obtaining an identity operation, we take into account the fact that we are working with two different rotating frames. The frequency of the qubit is in fact changing when $0 < t \le \tau$, so that we need to find a value for $\tau \gg 10$ ns such that the qubit performs an integer number of $2\pi z$ rotations in that time interval. The time evolution operator during this operation is represented by (h = 1)

$$U_{\text{Switch}}^{\text{RF}} = e^{i2\pi\Omega_Z\tau\sigma_z} e^{-i2\pi\int_0^\tau\sqrt{t_0^2 + E_M^2(t)}dt\sigma_z}, \qquad (\text{D4})$$

where $\Omega_Z = \sqrt{t_0^2 + (E_M^Z)^2}$ is the frequency of the qubit at the end of the protocol. Since approximately $\int_0^\tau \sqrt{t_0^2 + E_M^2(t)} dt \simeq \{\sqrt{t_0^2 + E_M^2(0)} + \sqrt{t_0^2 + E_M^2(\tau)}\} \tau/2 = (\Omega_X + \Omega_Z) \tau/2$, we obtain the condition

$$\tau = \left[\frac{1}{\tau} \int_0^\tau \sqrt{t_0^2 + E_M^2(t)} dt - \Omega_Z\right]^{-1} \simeq 2/|\Omega_X - \Omega_Z|.$$
(D5)

In our example of the E_M^X -to- E_M^Z switch, the timescale needed is $\tau \sim 1 \ \mu$ s. However, we can observe that we can think about a protocol where we switch E_M from E_M^X to E_M^Z first, implement the Z gate, and then switch the parameter back from E_M^Z to E_M^X , using the function $\tilde{E}_M(t) = E_M^X + (E_M^Z - E_M^X)(1 + \cos(\pi t/\tau))/2$. In this case, since the propagators for each step of this protocol represent z rotations and they all commute with each other, the effect of the E_M^Z -to- E_M^X switch,

$$\tilde{U}_{\text{Switch}}^{\text{RF}} = e^{i2\pi\,\Omega_X\,\tau\,\sigma_z} e^{-i2\pi\,\int_0^\tau \sqrt{t_0^2 + \tilde{E}_M^2(t)}dt\sigma_z},\qquad(\text{D6})$$

approximately cancels the contribution from the E_M^X -to- E_M^Z one, Eq. (D4), so that the propagator for the twogate sequence becomes $U_{XZ}^{\text{RF}}(t) = \tilde{U}_{\text{Switch}}^{\text{RF}} U_Z^{\text{RF}} U_Z^{\text{RF}} U_X^{\text{RF}}$, given that condition (D2) is fulfilled. We can conclude that, when we want to apply the XZ sequence to the Majorana transmon, we can decide to start and end the sequence in the system's configuration with $E_M = E_M^X$, so that the condition for having an identity operation during the switching of E_M is always fulfilled, while the adiabaticity criterion leads to the switching time's condition $\tau \gg 10$ ns. This is also valid for any two-gate sequence that includes a finite rotation about the z axis.

APPENDIX E: CHARGE 1/f NOISE DECOHERENCE RATE EXPRESSIONS

We derive the expressions for the dephasing and decoherence rates during free evolution used in Sec. IV, in particular Eqs. (21), (22), (24), and (26). In the literature, several works study the dissipative effects of the 1/f noise on the evolution of a two-level system [66,74,81,83]. However, the system considered in this work presents some noise contribution to the perpendicular component of the Hamiltonian, which is usually neglected. Here a more detailed review of the processes involved is desirable. We assume that the effect of the weak, stationary noise on a two-level system can be represented in the Hamiltonian by a classical stochastic perturbation of its longitudinal and transverse components. If we call $x_i(t)$ the variable along the *i* axis where the noise component $\delta x_i(t)$ is acting, the Hamiltonian evolving under free evolution can be approximated to $H[\delta x(t)] \simeq H_0 \sigma_z + V(t)$, with V(t) the term containing the noise fluctuations. In the case of the Majorana transmon we have $V(t) = V_z[\delta x_z(t)]\sigma_z + V_{\perp}[\delta x_{\perp}(t)]\sigma_v \equiv$ $V_z(t)\sigma_z + V_{\perp}(t)\sigma_v$. The Liouville equation in the interaction picture is $\partial_t \tilde{\rho}(t) = -(i/\hbar)[\tilde{V}(t), \tilde{\rho}(t)]$, with the density matrix given by $\tilde{\rho}(t) = e^{i(H_0t/\hbar)\sigma_z}\rho(t)e^{-i(H_0t/\hbar)\sigma_z}$, and $\tilde{V} = e^{i(H_0t/\hbar)\sigma_z}V(t)e^{-i(H_0t/\hbar)\sigma_z} \equiv V_z\sigma_z + V_{\perp}(e^{i(\Omega_0t-\pi/2)}\sigma_p^z + V_z)e^{i(\Omega_0t-\pi/2)}\sigma_p^z$ $e^{-i(\Omega_{01}t-\pi/2)}\sigma_m^z)$, where we have let $\Omega_{01}=2H_0/\hbar=$ E_{01}/\hbar , with E_{01} qubit energy splitting, and $\sigma_{p,m}^{z} = \frac{1}{2}(\sigma_{x} \pm$ $i\sigma_{v}$). The Liouville equation is iterated once and averaged over the noise ensemble, yielding

$$\dot{\tilde{\rho}}(t) = -\frac{1}{\hbar^2} \int_0^t dt' \left\langle \left[\tilde{V}(t), \left[\tilde{V}(t'), \tilde{\rho}(t') \right] \right] \right\rangle, \qquad (E1)$$

where we have set the noise average to zero, $\langle \tilde{V}(t) \rangle = 0$. This is widely assumed when calculating the decoherence rates, since every possible nonzero contribution can potentially be included in H_0 [79]. Since the noise source is weakly coupled to the two-level system, we can assume that it does not significantly change the components of the density operator within the evolution timescale; hence, we can approximate $\tilde{\rho}(t') \simeq \tilde{\rho}(t)$. The expressions of the diagonal and transverse components take the form

$$\dot{\tilde{\rho}}_{00,11}(t) = \pm \frac{2}{\hbar^2} \int_0^t dt' \{ \langle V_{\perp}(t) V_{\perp}(t') \rangle \cos[\Omega_{01}(t-t')] \\ \times (\tilde{\rho}_{11}(t) - \tilde{\rho}_{00}(t)) - \langle V_{\perp}(t) V_z(t') \rangle \\ \times e^{-i(\Omega_{01}t + \pi/2)} \tilde{\rho}_{01}(t) \\ - \langle V_{\perp}(t) V_z(t') \rangle e^{+i(\Omega_{01}t + \pi/2)} \tilde{\rho}_{10}(t) \}, \quad (E2a)$$

$$\begin{split} \dot{\tilde{\rho}}_{01}(t) &= +\frac{1}{\hbar^2} \int_0^t dt' \{ 2 \langle V_z(t) V_{\perp}(t') \rangle \, e^{i(\Omega_{01}t' + \pi/2)} \\ &\times (\tilde{\rho}_{11}(t) - \tilde{\rho}_{00}(t)) - 2 \langle V_{\perp}(t) V_{\perp}(t') \rangle \\ &\times e^{i\Omega_{01}(t-t')} \tilde{\rho}_{01}(t) + 2 \langle V_{\perp}(t) V_{\perp}(t') \rangle \\ &\times e^{i(\Omega_{01}(t+t') + \pi)} \tilde{\rho}_{10}(t) - 4 \langle V_z(t) V_z(t') \rangle \, \tilde{\rho}_{01}(t) \}, \end{split}$$
(E2b)

with $\dot{\rho}_{01}(t) = \dot{\rho}_{10}^*(t)$. It can be seen that, in Eqs. (E2), terms containing correlations between transverse and longitudinal components are present. However, for long times $t \gg 0$, we can apply the secular approximation and neglect the fast oscillating terms, so that we obtain three uncoupled differential equations. With regard to the diagonal elements, the expression for the polarization $\langle \sigma_z(t) \rangle = \frac{1}{2}(\rho_{11}(t) - \rho_{00}(t))$ can be obtained as

$$\langle \dot{\tilde{\sigma}}_{z}(t) \rangle = -\frac{4}{\hbar^{2}} \int_{0}^{t} \langle V_{\perp}(t) V_{\perp}(t') \rangle \cos[\Omega_{01}(t-t')] dt' \langle \tilde{\sigma}_{z}(t) \rangle,$$
(E3)

while, for the coherence term $\rho_{01}(t)$, we have

$$\dot{\tilde{\rho}}_{01}(t) = -\frac{1}{\hbar^2} \int_0^t dt' \{ 2 \langle V_{\perp}(t) V_{\perp}(t') \rangle e^{+i\Omega_{01}(t-t')} + 4 \langle V_z(t) V_z(t') \rangle \} \tilde{\rho}_{01}(t).$$
(E4)

When these expressions are formally integrated, they lead to the form of the density matrix presented in Sec. IV and to Eqs. (21) and (22). To integrate these equations, we expand V_{\perp} and V_z to first order in the noise, $V_{\perp}(t) \simeq (\partial V_{\perp}[x_{\perp}(t)]/\partial x_{\perp})\delta x_{\perp}$ and $V_z(t) \simeq$ $(\partial V_z[x_z(t)]/\partial x_z)\delta x_z$. We also make use of the following relations between the autocorrelation $C_x(\tau) =$ $\langle \delta x(0)\delta x(\tau) \rangle$ and the PSD $S_x(\omega)$ of the stochastic variable δx :

$$S_x(\omega) = \frac{1}{2\pi} \int_{-\infty}^{+\infty} C_x(\tau) e^{i\omega\tau} d\tau, \qquad (E5)$$

$$C_x(\tau) = \int_{-\infty}^{+\infty} S_x(\omega) e^{-i\omega\tau} d\omega.$$
 (E6)

Integrating Eqs. (E3) and (E4) yields integrals of the form $\int_0^t dt'' \int_0^{t''} dt' F(t'', t')$ with *F* a function of *t'* and *t''*. When the integrand F(t'', t') is symmetric by exchange of *t'*, *t''*, we have

$$\int_0^t dt'' \int_0^{t''} dt' F(t'',t') = \frac{1}{2} \int_0^t dt'' \int_0^t dt' F(t'',t').$$

This is true for $\langle \tilde{\sigma}_z(t) \rangle$, and its integration leads to the form $\langle \tilde{\sigma}_z(t) \rangle = e^{G(t)} \langle \tilde{\sigma}_z(0) \rangle$ and to the Bloch-Redfield exponential decaying function. Since we assume the noise stationary, we can write $\langle \delta x_{\perp}(t') \delta x_{\perp}(t') \rangle = \langle \delta x_{\perp}(0) \delta x_{\perp}(t'-t'') \rangle = C_{x_{\perp}}(t'-t'')$ and make the change of variables $\tau = t' - t''$ and T/2 = t' + t''. Using the definition of the power spectral density given above, in the limit of $t \to \infty$ we get

$$G(t) = -\frac{2}{\hbar^2} \left| \frac{\partial V_\perp}{\partial x_\perp} \right|^2 \int_0^t dt'' \int_0^t dt' \left\langle \delta x_\perp(t'') \delta x_\perp(t') \right\rangle$$

× cos[$\Omega_{01}(t'' - t')$]
$$\simeq -\frac{1}{\hbar^2} \left| \frac{\partial V_\perp}{\partial x_\perp} \right|^2 t (2\pi S_{x_\perp}(E_{01}/\hbar) + 2\pi S_{x_\perp}(-E_{01}/\hbar))$$

$$= -\frac{4\pi}{\hbar^2} \left| \frac{\partial V_\perp}{\partial x_\perp} \right|^2 S_{x_\perp}(E_{01}/\hbar) t$$

= $-\Gamma_1 t,$ (E7)

which is Eq. (24) in Sec. IV. The evolution of the populations in the limit of zero temperature is thus given by $\tilde{\rho}_{11,00} = \frac{1}{2} \pm \langle \tilde{\sigma}_z(t) \rangle = \frac{1}{2} \pm \langle \tilde{\sigma}_z(0) \rangle e^{-\Gamma_1 t}$. Regarding the evolution of $\tilde{\rho}_{01}$, the integration of

Regarding the evolution of $\tilde{\rho}_{01}$, the integration of Eq. (E4) yields a decaying function that is still of the form $\tilde{\rho}_{01}(t) = e^{A(t)}\tilde{\rho}_{01}(0)$, with the exponent A(t) given by

$$A(t) = -\frac{2}{\hbar^2} \int_0^t dt'' \int_0^{t''} dt' \left\langle V_{\perp}(t'') V_{\perp}(t') \right\rangle e^{+i\Omega_{01}(t''-t')} -\frac{4}{\hbar^2} \int_0^t dt'' \int_0^{t''} dt' \left\langle V_z(t'') V_z(t') \right\rangle.$$
(E8)

The first term in the integral is not symmetric by exchange of t' and t", but it can be expressed as the sum of a symmetric, real term $\propto \cos[\Omega_{01}(t'' - t')]$ and an antisymmetric, imaginary one $\propto i \sin[\Omega_{01}(t'' - t')]$. The latter introduces a phase factor in $\rho_{01}(t)$ and does not contribute to the dephasing. The real part can be solved in the same way as the relaxation factor was calculated above, leading to

$$-\frac{1}{2\hbar^2} \left| \frac{\partial V_\perp}{\partial x_\perp} \right|^2 \int_0^t dt'' \int_0^t dt' \left\langle \delta x_\perp(0) \delta x_\perp(t'-t'') \right\rangle$$
$$\times \left(e^{i\Omega_{01}(t''-t')} + e^{-i\Omega_{01}(t''-t')} \right) = -\frac{\Gamma_1}{2}t. \tag{E9}$$

The $V_z(t')V_z(t')$ term contributes to the pure dephasing and can be integrated as follows [74]:

$$-\frac{2}{\hbar^{2}}\left|\frac{\partial V_{z}}{\partial x_{z}}\right|^{2}\int_{0}^{t}dt''\int_{0}^{t}dt'\,\langle\delta x_{z}(t'')\delta x_{z}(t')\rangle$$

$$=-\frac{2}{\hbar^{2}}\left|\frac{\partial V_{z}}{\partial x_{z}}\right|^{2}\int_{-\infty}^{+\infty}d\omega S_{x_{z}}(\omega)\int_{0}^{t}dt''e^{i\omega t''}\int_{0}^{t}dt'e^{-i\omega t'}$$

$$=-\frac{4}{\hbar^{2}}\left|\frac{\partial V_{z}}{\partial x_{z}}\right|^{2}\left(\int_{0}^{+\infty}S_{x_{z}}(\omega)\operatorname{sinc}^{2}(\omega t/2)d\omega\right)t^{2}.$$
(E10)

Here the integral of the PSD depends on the spectral characteristics of the noise δx_z . Usually, the 1/f noise in superconducting systems is treated as static noise, which is valid for $\omega_{IR} \ll \omega_{UV} \ll 1/t$, with ω_{IR} and ω_{UV} the PSD cutoffs. When, in the Majorana transmon, the dephasing due to 1/fnoise affecting the offset charge n_g is numerically simulated, with the noise frequency within the range 10 Hz < f < 50 MHz, we obtain $T_2^* \sim 10 \ \mu s$, corresponding to $1/T_2^* \sim 100$ kHz. The noise cannot be considered static in this case and another approach is needed [74]. The contribution of the function $\operatorname{sinc}^2(\omega t/2)$ is mostly restricted to $\omega < 2\pi/t$. Since $S(\omega)$ is also peaked at $\omega \sim 0$, it is reasonable to restrict the integral to the frequency range $\omega_{IR} < \omega < 2\pi/t$. When approximating $\operatorname{sinc}(\omega t/2) \simeq \cos^2(\omega t/2)$, we obtain

$$\int_{0}^{+\infty} \frac{1}{\omega} \operatorname{sinc}^{2}(\omega t/2) d\omega$$
$$\simeq \int_{\omega_{\mathrm{IR}}}^{2\pi/t} \frac{1}{\omega} \cos^{2}(\omega t/2) d\omega = \int_{\omega_{\mathrm{IR}}t/2}^{\pi} \frac{\cos^{2}(y)}{y} dy$$
$$= -\frac{1}{2} \operatorname{Ci}(\omega_{\mathrm{IR}}t) + \frac{1}{2} \operatorname{Ci}(2\pi) + \frac{1}{2} \ln(2\pi/\omega_{\mathrm{IR}}t)$$
$$\simeq \ln\left(\frac{2\pi}{\omega_{\mathrm{IR}}t}\right) + O(1), \tag{E11}$$

where Ci(x) is the cosine integral. The expression for the dephasing factor is therefore given by

$$|e^{A(t)}| = \exp\left\{-\frac{2\pi}{\hbar^2} \left|\frac{\partial V_{\perp}}{\partial x_{\perp}}\right|^2 S_{x_{\perp}}(E_{01}/\hbar)t - \frac{4}{\hbar^2} \left|\frac{\partial V_z}{\partial x_z}\right|^2 \alpha \ln\left(\frac{2\pi}{\omega_{\rm IR}t}\right)t^2\right\}, \quad (E12)$$

which is the expression used for calculating the pure dephasing factor $|f_z| = e^{-\chi(t)}$ in Eq. (26).

- Y. Nakamura, Y. A. Pashkin, and J. S. Tsai, Coherent control of macroscopic quantum states in a single-Cooper-pair box, Nature **398**, 786 (1999).
- [2] A. Blais, R.-S. Huang, A. Wallraff, S. M. Girvin, and R. J. Schoelkopf, Cavity quantum electrodynamics for superconducting electrical circuits: an architecture for quantum computation, Phys. Rev. A 69, 62320 (2004).
- [3] J. Koch, T. M. Yu, J. Gambetta, A. A. Houck, D. I. Schuster, J. Majer, A. Blais, M. H. Devoret, S. M. Girvin, and R. J. Schoelkopf, Charge-insensitive qubit design derived from the Cooper pair box, Phys. Rev. A 76, 042319 (2007).
- [4] P. Krantz, M. Kjaergaard, F. Yan, T. P. Orlando, S. Gustavsson, and W. D. Oliver, A quantum engineer's guide to superconducting qubits, Appl. Phys. Rev. 6, 021318 (2019).

- [5] M. Kjaergaard, M. E. Schwartz, J. Braumüller, P. Krantz, J. I.-J. Wang, S. Gustavsson, and W. D. Oliver, Superconducting qubits: current state of play, Annu. Rev. Condens. Matter Phys. 11, 369 (2020).
- [6] X. Y. Jin, A. Kamal, A. P. Sears, T. Gudmundsen, D. Hover, J. Miloshi, R. Slattery, F. Yan, J. Yoder, T. P. Orlando, S. Gustavsson, and W. D. Oliver, Thermal and Residual Excited-State Population in a 3D Transmon Qubit, Phys. Rev. Lett. 114, 240501 (2015).
- [7] F. Yan, S. Gustavsson, A. Kamal, J. Birenbaum, A. P. Sears, D. Hover, T. J. Gudmundsen, D. Rosenberg, G. Samach, S. Weber, J. L. Yoder, T. P. Orlando, J. Clarke, A. J. Kerman, and W. D. Oliver, The flux qubit revisited to enhance coherence and reproducibility, Nat. Commun. 7, 12964 (2016).
- [8] L. B. Nguyen, Y.-H. Lin, A. Somoroff, R. Mencia, N. Grabon, and V. E. Manucharyan, High-Coherence Fluxonium Qubit, Phys. Rev. X 9, 041041 (2019).
- [9] A. Grimm, N. E. Frattini, S. Puri, S. O. Mundhada, S. Touzard, M. Mirrahimi, S. M. Girvin, S. Shankar, and M. H. Devoret, Stabilization and operation of a Kerr-cat qubit, Nature 584, 205 (2020).
- [10] A. Gyenis, P. S. Mundada, A. Di Paolo, T. M. Hazard, X. You, D. I. Schuster, J. Koch, A. Blais, and A. A. Houck, Experimental Realization of a Protected Superconducting Circuit Derived from the $0-\pi$ Qubit, PRX Quantum 2, 010339 (2021).
- [11] J. Preskill, in *Introduction to Quantum Computation and Information*, edited by H.-K. Lo, T. Spiller, and S. Popescu (World Scientific, Singapore, 1998).
- [12] T. W. Larsen, K. D. Petersson, F. Kuemmeth, T. S. Jespersen, P. Krogstrup, J. Nygård, and C. M. Marcus, Semiconductor-Nanowire-Based Superconducting Qubit, Phys. Rev. Lett. 115, 127001 (2015).
- [13] L. Casparis, T. W. Larsen, M. S. Olsen, F. Kuemmeth, P. Krogstrup, J. Nygård, K. D. Petersson, and C. M. Marcus, Gatemon Benchmarking and Two-Qubit Operations, Phys. Rev. Lett. 116, 150505 (2016).
- [14] F. Luthi, T. Stavenga, O. W. Enzing, A. Bruno, C. Dickel, N. K. Langford, M. A. Rol, T. S. Jespersen, J. Nygård, P. Krogstrup, and L. DiCarlo, Evolution of Nanowire Transmon Qubits and Their Coherence in a Magnetic Field, Phys. Rev. Lett. **120**, 100502 (2018).
- [15] L. Casparis, M. R. Connolly, M. Kjaergaard, N. J. Pearson, A. Kringhøj, T. W. Larsen, F. Kuemmeth, T. Wang, C. Thomas, S. Gronin, G. C. Gardner, M. J. Manfra, C. M. Marcus, and K. D. Petersson, Superconducting gatemon qubit based on a proximitized two-dimensional electron gas, Nat. Nanotech. 13, 915 (2018).
- [16] L. Casparis, N. J. Pearson, A. Kringhøj, T. W. Larsen, F. Kuemmeth, J. Nygård, P. Krogstrup, K. D. Petersson, and C. M. Marcus, Voltage-controlled superconducting quantum bus, Phys. Rev. B 99, 085434 (2019).
- [17] T. W. Schmitt, M. R. Connolly, M. Schleenvoigt, C. Liu, O. Kennedy, A. R. Jalil, B. Bennemann, S. Trellenkamp, F. Lentz, E. Neumann, T. Lindström, S. E. de Graaf, E. Berenschot, N. Tas, G. Mussler, K. D. Petersson, D. Grützmacher, and P. Schüffelgen, Integration of selectively grown topological insulator nanoribbons in superconducting quantum circuits, (2020), ArXiv:2007.04224.

- [18] M. Hays, V. Fatemi, D. Bouman, J. Cerrillo, S. Diamond, K. Serniak, T. Connolly, P. Krogstrup, J. Nygård, A. L. Yeyati, A. Geresdi, and M. H. Devoret, Coherent manipulation of an Andreev spin qubit, Science **373**, 430 (2021).
- [19] N. Read and D. Green, Paired states of fermions in two dimensions with breaking of parity and time-reversal symmetries and the fractional quantum Hall effect, Phys. Rev. B 61, 10267 (2000).
- [20] A. Y. Kitaev, Unpaired Majorana fermions in quantum wires, Phys.-Usp. 44, 131 (2001).
- [21] J. Alicea, New directions in the pursuit of Majorana fermions in solid state systems, Rep. Prog. Phys. 75, 76501 (2012).
- [22] L. Fu and C. L. Kane, Superconducting Proximity Effect and Majorana Fermions at the Surface of a Topological Insulator, Phys. Rev. Lett. 100, 96407 (2008).
- [23] A. R. Akhmerov, J. Nilsson, and C. W. J. Beenakker, Electrically Detected Interferometry of Majorana Fermions in a Topological Insulator, Phys. Rev. Lett. **102**, 216404 (2009).
- [24] R. M. Lutchyn, J. D. Sau, and S. Das Sarma, Majorana Fermions and a Topological Phase Transition in Semiconductor-Superconductor Heterostructures, Phys. Rev. Lett. 105, 077001 (2010).
- [25] Y. Oreg, G. Refael, and F. von Oppen, Helical Liquids and Majorana Bound States in Quantum Wires, Phys. Rev. Lett. 105, 177002 (2010).
- [26] A. Cook and M. Franz, Majorana fermions in a topologicalinsulator nanowire proximity-coupled to an s-wave superconductor, Phys. Rev. B 84, 201105 (2011).
- [27] G.-Y. Huang and H. Q. Xu, Majorana fermions in topological-insulator nanowires: from single superconducting nanowires to Josephson junctions, Phys. Rev. B 95, 155420 (2017).
- [28] J. Manousakis, A. Altland, D. Bagrets, R. Egger, and Y. Ando, Majorana qubits in a topological insulator nanoribbon architecture, Phys. Rev. B 95, 165424 (2017).
- [29] K. Yavilberg, E. Ginossar, and E. Grosfeld, Differentiating Majorana from Andreev bound states in a superconducting circuit, Phys. Rev. B 100, 241408 (2019).
- [30] J. Ávila, E. Prada, P. San-Jose, and R. Aguado, Superconducting islands with topological Josephson junctions based on semiconductor nanowires, Phys. Rev. B 102, 094518 (2020).
- [31] J. Ávila, E. Prada, P. San-Jose, and R. Aguado, Majorana oscillations and parity crossings in semiconductor nanowire-based transmon qubits, Phys. Rev. Res. 2, 033493 (2020).
- [32] E. Prada, P. San-Jose, M. W. A. de Moor, A. Geresdi, E. J. H. Lee, J. Klinovaja, D. Loss, J. Nygård, R. Aguado, and L. P. Kouwenhoven, From Andreev to Majorana bound states in hybrid superconductor-semiconductor nanowires, Nat. Rev. Phys. 2, 575 (2020).
- [33] H. Tan, P.-H. Fu, Y.-R. Chen, J.-F. Liu, J. Wang, and Z. Ma, Quantized Majorana pump in semiconductorsuperconductor heterostructures, Phys. Rev. B 103, 195407 (2021).
- [34] V. Mourik, K. Zuo, S. M. Frolov, S. R. Plissard, E. P. A. M. Bakkers, and L. P. Kouwenhoven, Signatures of Majorana fermions in hybrid superconductor-semiconductor nanowire devices, Science 336, 1003 (2012).

- [35] L. P. Rokhinson, X. Liu, and J. K. Furdyna, The fractional a.c. Josephson effect in a semiconductor-superconductor nanowire as a signature of Majorana particles, Nat. Phys. 8, 795 (2012).
- [36] M. T. Deng, S. Vaitiekėnas, E. B. Hansen, J. Danon, M. Leijnse, K. Flensberg, J. Nygård, P. Krogstrup, and C. M. Marcus, Majorana bound state in a coupled quantum-dot hybrid-nanowire system, Science 354, 1557 (2016).
- [37] F. Nichele, A. C. C. Drachmann, A. M. Whiticar, E. C. T. O'Farrell, H. J. Suominen, A. Fornieri, T. Wang, G. C. Gardner, C. Thomas, A. T. Hatke, P. Krogstrup, M. J. Manfra, K. Flensberg, and C. M. Marcus, Scaling of Majorana Zero-Bias Conductance Peaks, Phys. Rev. Lett. 119, 136803 (2017).
- [38] D. Laroche, D. Bouman, D. J. van Woerkom, A. Proutski, C. Murthy, D. I. Pikulin, C. Nayak, R. J. J. van Gulik, J. Nygård, P. Krogstrup, L. P. Kouwenhoven, and A. Geresdi, Observation of the 4-periodic Josephson effect in indium arsenide nanowires, Nat. Commun. 10, 245 (2019).
- [39] S. Vaitiekėnas, G. W. Winkler, B. van Heck, T. Karzig, M.-T. Deng, K. Flensberg, L. I. Glazman, C. Nayak, P. Krogstrup, R. M. Lutchyn, and C. M. Marcus, Flux-induced topological superconductivity in full-shell nanowires, Science 367, eaav3392 (2020).
- [40] J. R. Williams, A. J. Bestwick, P. Gallagher, S. S. Hong, Y. Cui, A. S. Bleich, J. G. Analytis, I. R. Fisher, and D. Goldhaber-Gordon, Unconventional Josephson Effect in Hybrid Superconductor-Topological Insulator Devices, Phys. Rev. Lett. **109**, 056803 (2012).
- [41] M. Veldhorst, M. Snelder, M. Hoek, T. Gang, V. K. Guduru, X. L. Wang, U. Zeitler, W. G. van der Wiel, A. A. Golubov, H. Hilgenkamp, and A. Brinkman, Josephson supercurrent through a topological insulator surface state, Nat. Mater. 11, 417 (2012).
- [42] L. Galletti, S. Charpentier, M. Iavarone, P. Lucignano, D. Massarotti, R. Arpaia, Y. Suzuki, K. Kadowaki, T. Bauch, A. Tagliacozzo, F. Tafuri, and F. Lombardi, Influence of topological edge states on the properties of Al/Bi₂Se₃/Al hybrid Josephson devices, Phys. Rev. B 89, 134512 (2014).
- [43] C. Kurter, A. Finck, Y. S. Hor, and D. J. V. Harlingen, Evidence for an anomalous current–phase relation in topological insulator Josephson junctions, Nat. Commun. 6, 7130 (2015).
- [44] S. Charpentier, L. Galletti, G. Kunakova, R. Arpaia, Y. Song, R. Baghdadi, S. M. Wang, A. Kalaboukhov, E. Olsson, F. Tafuri, D. Golubev, J. Linder, T. Bauch, and F. Lombardi, Induced unconventional superconductivity on the surface states of Bi₂Te₃ topological insulator, Nat. Commun. 8, 2019 (2017).
- [45] J. Alicea, Y. Oreg, G. Refael, F. von Oppen, and M. P. A. Fisher, Non-Abelian statistics and topological quantum information processing in 1D wire networks, Nat. Phys. 7, 412 (2011).
- [46] K. Flensberg, Non-Abelian Operations on Majorana Fermions via Single-Charge Control, Phys. Rev. Lett. 106, 90503 (2011).
- [47] F. Hassler, A. R. Akhmerov, and C. W. J. Beenakker, The top-transmon: a hybrid superconducting qubit for parityprotected quantum computation, New J. Phys. 13, 095004 (2011).

- [48] B. van Heck, A. R. Akhmerov, F. Hassler, M. Burrello, and C. W. J. Beenakker, Coulomb-assisted braiding of Majorana fermions in a Josephson junction array, New J. Phys. 14, 035019 (2012).
- [49] E. Ginossar and E. Grosfeld, Microwave transitions as a signature of coherent parity mixing effects in the Majorana-transmon qubit, Nat. Commun. 5, 4772 (2014).
- [50] K. Yavilberg, E. Ginossar, and E. Grosfeld, Fermion parity measurement and control in Majorana circuit quantum electrodynamics, Phys. Rev. B 92, 075143 (2015).
- [51] S. Plugge, A. Rasmussen, R. Egger, and K. Flensberg, Majorana box qubits, New J. Phys. 19, 12001 (2017).
- [52] T. Karzig, C. Knapp, R. M. Lutchyn, P. Bonderson, M. B. Hastings, C. Nayak, J. Alicea, K. Flensberg, S. Plugge, Y. Oreg, C. M. Marcus, and M. H. Freedman, Scalable designs for quasiparticle-poisoning-protected topological quantum computation with Majorana zero modes, Phys. Rev. B 95, 235305 (2017).
- [53] B. Bauer, T. Karzig, R. Mishmash, A. Antipov, and J. Alicea, Dynamics of Majorana-based qubits operated with an array of tunable gates, SciPost Phys. 5, 4 (2018).
- [54] T. Li, W. A. Coish, M. Hell, K. Flensberg, and M. Leijnse, Four-Majorana qubit with charge readout: dynamics and decoherence, Phys. Rev. B 98, 205403 (2018).
- [55] M. S. Scheurer and A. Shnirman, Nonadiabatic processes in Majorana qubit systems, Phys. Rev. B 88, 064515 (2013).
- [56] R. V. Mishmash, B. Bauer, F. von Oppen, and J. Alicea, Dephasing and leakage dynamics of noisy Majorana-based qubits: topological versus Andreev, Phys. Rev. B 101, 075404 (2020).
- [57] M. I. K. Munk, J. Schulenborg, R. Egger, and K. Flensberg, Parity-to-charge conversion in Majorana qubit readout, Phys. Rev. Res. 2, 033254 (2020).
- [58] J. F. Steiner and F. von Oppen, Readout of Majorana qubits, Phys. Rev. Res. 2, 033255 (2020).
- [59] V. Derakhshan Maman, M. Gonzalez-Zalba, and A. Pályi, Charge Noise and Overdrive Errors in Dispersive Readout of Charge, Spin, and Majorana Qubits, Phys. Rev. Appl. 14, 064024 (2020).
- [60] J. I. Väyrynen, D. I. Pikulin, and R. M. Lutchyn, Majorana signatures in charge transport through a topological superconducting double-island system, Phys. Rev. B 103, 205427 (2021).
- [61] T. B. Smith, M. C. Cassidy, D. J. Reilly, S. D. Bartlett, and A. L. Grimsmo, Dispersive Readout of Majorana Qubits, PRX Quantum 1, 020313 (2020).
- [62] Z. Wang, W.-C. Huang, Q.-F. Liang, and X. Hu, Landau-Zener-Stückelberg interferometry for Majorana qubit, Sci. Rep. 8, 7920 (2018).
- [63] A. L. Grimsmo and T. B. Smith, Majorana qubit readout using longitudinal qubit-resonator interaction, Phys. Rev. B 99, 235420 (2019).
- [64] C. Ohm and F. Hassler, Microwave readout of Majorana qubits, Phys. Rev. B 91, 085406 (2015).
- [65] Z. Lü and H. Zheng, Effects of counter-rotating interaction on driven tunneling dynamics: coherent destruction of tunneling and Bloch-Siegert shift, Phys. Rev. A 86, 23831 (2012).

- [66] C. Knapp, T. Karzig, R. M. Lutchyn, and C. Nayak, Dephasing of Majorana-based qubits, Phys. Rev. B 97, 125404 (2018).
- [67] T. Karzig, W. S. Cole, and D. I. Pikulin, Quasiparticle Poisoning of Majorana Qubits, Phys. Rev. Lett. **126**, 057702 (2021).
- [68] A. Messiah, *Quantum Mechanics, Volume II* (North Holland, Amsterdam, 1975).
- [69] M. Abramowitz, I. A. Stegun, eds., Handbook of mathematical functions: with formulas, graphs, and mathematical tables, 9th ed., Dover books on mathematics (Dover Publ, New York, NY, 2013).
- [70] A. B. Klimov and S. M. Chumakov, A Group-Theoretical Approach to Quantum Optics (Wiley, Weinheim, 2009).
- [71] M. Sillanpää, T. Lehtinen, A. Paila, Y. Makhlin, and P. Hakonen, Continuous-Time Monitoring of Landau-Zener Interference in a Cooper-Pair Box, Phys. Rev. Lett. 96, 187002 (2006).
- [72] M. A. Nielsen and I. L. Chuang, *Quantum Computation and Quantum Information, Cambridge Series on Informa*tion and the Natural Sciences (Cambridge University Press, Cambridge, 2000).
- [73] S. Bravyi and A. Kitaev, Universal quantum computation with ideal Clifford gates and noisy ancillas, Phys. Rev. A 71, 022316 (2005).
- [74] G. Ithier, E. Collin, P. Joyez, P. J. Meeson, D. Vion, D. Esteve, F. Chiarello, A. Shnirman, Y. Makhlin, J. Schriefl, and G. Schön, Decoherence in a superconducting quantum bit circuit, Phys. Rev. B 72, 134519 (2005).
- [75] L. Sun, L. DiCarlo, M. D. Reed, G. Catelani, L. S. Bishop, D. I. Schuster, B. R. Johnson, G. A. Yang, L. Frunzio, L. Glazman, M. H. Devoret, and R. J. Schoelkopf, Measurements of Quasiparticle Tunneling Dynamics in a Band-Gap-Engineered Transmon Qubit, Phys. Rev. Lett. 108, 230509 (2012).
- [76] M. Hays, G. de Lange, K. Serniak, D. J. van Woerkom, D. Bouman, P. Krogstrup, J. Nygård, A. Geresdi, and M. H. Devoret, Direct Microwave Measurement of Andreev-Bound-State Dynamics in a Semiconductor-Nanowire Josephson Junction, Phys. Rev. Lett. **121**, 047001 (2018).
- [77] F. Bloch, Generalized theory of relaxation, Phys. Rev. 105, 1206 (1957).
- [78] A. G. Redfield, On the theory of relaxation processes, IBM J. Res. Dev. 1, 19 (1957).
- [79] C. Cohen-Tannoudji, G. Grynberg, and J. Dupont-Roc, *Atom-Photon Interactions: Basic Processes and Applications* (Wiley, New York, 1992).
- [80] U. Weiss, *Quantum Dissipative Systems*, Series in Modern Condensed Matter Physics, Vol. 10 (World Scientific, Singapore, 1999).
- [81] Y. Makhlin, G. Schön, and A. Shnirman, Dissipative effects in Josephson qubits, Chem. Phys. 296, 315 (2004).
- [82] Y. Makhlin and A. Shnirman, Dephasing of Solid-State Qubits at Optimal Points, Phys. Rev. Lett. 92, 178301 (2004).
- [83] A. Shnirman, Y. Makhlin, and G. Schön, Noise and decoherence in quantum two-level systems, Phys. Scr. T102, 147 (2002).
- [84] F. K. Wilhelm, M. J. Storcz, U. Hartmann, and M. R. Geller, in *Manipulating Quantum Coherence in Solid State Systems* (Springer, Dordrecht, 2007), p. 195.

- [85] J. J. Burnett, A. Bengtsson, M. Scigliuzzo, D. Niepce, M. Kudra, P. Delsing, and J. Bylander, Decoherence benchmarking of superconducting qubits, npj Quantum Inf. 5, 54 (2019).
- [86] J. Q. You, X. Hu, S. Ashhab, and F. Nori, Low-decoherence flux qubit, Phys. Rev. B 75, 140515 (2007).
- [87] A. Uhlmann, The "transition probability" in the state space of a *-algebra, Rep. Math. Phys. 9, 273 (1976).
- [88] M. D. Bowdrey, D. K. Oi, A. J. Short, K. Banaszek, and J. A. Jones, Fidelity of single qubit maps, Phys. Lett. A 294, 258 (2002).
- [89] A. Cottet, *Implementation of a quantum bit in a superconducting circuit*, Ph.D. thesis, Université Paris VI (2002).
- [90] F. Motzoi, J. M. Gambetta, S. T. Merkel, and F. K. Wilhelm, Optimal control methods for rapidly time-varying Hamiltonians, Phys. Rev. A **84**, 022307 (2011).